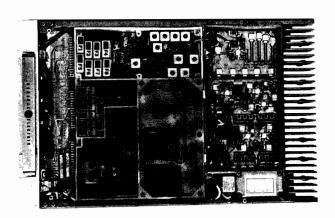


MASTR II MAINTENANCE MANUAL

406-420 & 450-512 MHz, 40-WATT TRANSMITTER



SPECIFICATIONS *

Power Output

406-420 MHz & 450-470 MHz

470-494 MHz

494-512 MHz

Crystal Multiplication Factor

Frequency Stability

5C-ICOM with EC-ICOM 5C-ICOM or EC-ICOM

2C-ICOMS

Spurious and Harmonic Emission

Modulation

Modulation Sensitivity

Audio Frequency Characteristics

Distortion

Deviation Symmetry

Maximum Frequency Spread (2 to 8 channels)

406-420 MHz

450-470 MHz

470-494 MHz

494-512 MHz

Duty Cycle

RF Output Impedance

40 Watts (Adjustable from 12 to 40 Watts)

38 Watts (Adjustable from 12 to 38 Watts)

35 Watts (Adjustable from 12 to 35 Watts)

36

 $\pm 0.0005\%$ (-40°C to +70°C)

±0.0002% (0°C to +55°C) ±0.0002% (-40°C to +70°C)

At least 80 dB below full rated power output.

Adjustable from 0 to ±5 kHz swing with instantaneous modulation limiting.

75 to 120 Millivolts

Within +1 dB to -3 dB of a 6-dB/octave preemphasis from 300 to 3000 Hz per EIA standards. Post limiter filter per FCC and EIA.

Less than 2% (1000 Hz) Less than 3% (300 to 3000 Hz)

0.5 kHz maximum

Full Specifications

1 dB Degradation

2.75 MHz

2.75 MHz

9.00 MHz

2.90 MHz

9.50 MHz

6.00 MHz

3.00 MHz

9.75 MHz

EIA 20% Intermittent

50 Ohms

mese specifications are intended primarily for the use of the serviceman. Refer to the appropriate Specification Sheet for the complete specifications.



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-WARNING-

Although the highest DC voltage in MASTR II Mobile Equipment is supplied by the vehicle battery, high currents may be drawn under short circuit conditions. These currents can possibly heat metal objects such as tools, rings, watchbands, etc., enough to cause burns. Be careful when working near energized circuits! High-level RF energy in the transmitter Power Amplifier assembly can cause RF burns upon contact. KEEP AWAY FROM THESE CIRCUITS WHEN THE TRANSMITTER IS ENERGIZED!

DESCRIPTION

MASTR II transmitters are crystal-controlled, phase modulated transmitters designed for one through eight-frequency operation in the 406 to 420 and 450 to 512 megahertz band. The solid state transmitter utilizes both integrated circuits (ICs) and discrete components, and consists of the following assemblies:

Exciter Board; with audio, modulator, amplifier and multiplier stages

Power Amplifier Assembly; with amplifier, driver, PA, power control, filter and antenna switch.

CIRCUIT ANALYSIS

EXCITER

The exciter uses seven transistors and one integrated circuit to drive the PA assembly. The exciter can be equipped with up to eight Integrated Circuit Oscillator Modules (ICOMs). The ICOM crystal frequency ranges from approximately 11.3 to 14.2 megahertz, and the crystal frequency is multiplied 36 times.

Audio, supply voltages and control functions are connected from the system board to the exciter board through P902.

Centralized metering jack J103 is provided fro use with GE Test Set Model 4EX3All or Test Kit 4EX8Kl2. The test set meters the modulator, multiplier and amplifier stages, and the regulated 10-Volts.

ICOMS

Three different types of ICOMs are available for use in the exciter. Each of the ICOMs contains a crystal-controlled Colpitts oscillator, and two of the ICOMs contain compensator ICs. The different ICOMs are:

5C-ICOM - contains an oscillator and a 5 part-per-million (±0.0005%) compensator IC. Provides compensation for EC-ICOMs.

EC-ICOM - contains an oscillator only. Requires external compensation from a 5C-ICOM.

2C-ICOM - contains an oscillator only. 2 PPM ($\pm 0.0002\%$) compensator IC. Will not provide compensation for an EC-ICOM.

The ICOMs are enclosed in an RF shielded can with the type ICOM (5C-ICOM, EC-ICOM or 2C-ICOM) printed on the top of the can. Access to the oscillator trimmer is obtained by prying up the plastic tab on the top of the can. The tabs can also be used to pull the ICOMs out of the radio.

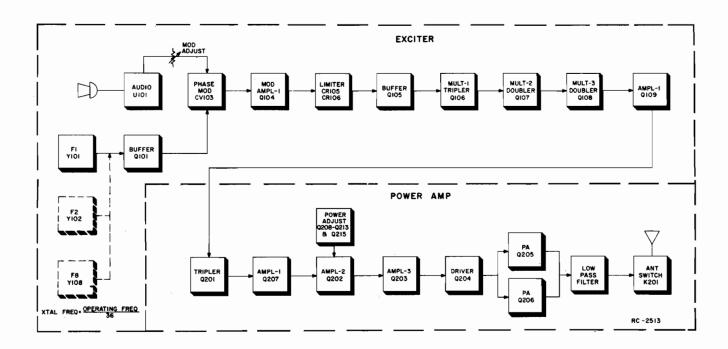


Figure 1 - Transmitter Block Diagram

Frequency selection is accomplished by switching the ICOM keying lead (terminal 6) to A- by means of the frequency selector switch on the control unit. In single-frequency radios, a jumper from H9 to H10 in the control unit connects terminal 6 of the ICOM to A-. The oscillator is turned on by applying a keyed +10 Volts to the external oscillator load resistor.

-CAUTION-

All ICOMs are individually compensated at the factory and cannot be repaired in the field. Any attempt to repair or change an ICOM frequency will void the warranty.

In Standard 5 PPM radios using EX-ICOMs, at least one 5C-ICOM must be used. The 5C-ICOM is normally used in the receiver Fl position, but can be used in any transmit or receive position. One 5C-ICOM can provide compensation for up to 15 EC-ICOMs in the transmit and receiver. Should the 5C-ICOM compensator fail in the open mode, the EC-ICOMs will still maintain 2 PPM frequency stability from 0°C to 55°C (+32°F to 131°F) due to the regulated compensation voltage (5 Volts) from the 10-Volt regulator IC. If desired, up to 16 5C-ICOMs may be used in the radio.

The 2C-ICOMs are self-compensated at 2 PPM and will not provide compensation for EC-ICOMs.

Oscillator Circuit

The quartz crystals used in ICOMs exhibit the traditional "S" curve characteristics of output frequency versus operating temperature.

At both the coldest and hottest temperatures, the frequency increases with increasing temperature. In the middle termperature range (approximately 0°C to 55°C), frequency decreases with increasing temperature.

Since the rate of change is nearly linear over the mid-temperature range, the output frequency change can be compensated by choosing a parallel compensation capacitor with a temperature coefficient approximately equal and opposite that of the crystal.

Figure 2 shows the typical performance of an uncompensated crystal as well as the typical performance of a crystal which has been matched with a properly chosen compensation capacitor.

At temperatures above and below the mid-range, additional compensation must be introduced. An externally generated compensation voltage is applied to a varactor (voltage-variable capacitor) which is in parallel with the crystal.

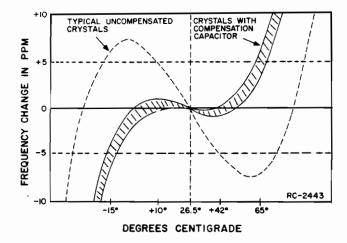


Figure 2 - Typical Crystal Characteristics

A constant bias of 5 Volts (provided from Regulator IC U901 in parallel with the compensator) establishes the varactor capacity at a constant value over the entire mid-temperature range. With no additional compensation, all of the oscillators will provide 2 PPM frequency stability from 0°C to 55°C (+32°F to 131°F).

Compensator Circuits

Both the 5C-ICOMs and 2C-ICOMs are temperature compensated at both ends of the temperature range to provide instant frequency compensation. An equivalent ICOM circuit is shown in Figure 3.

The cold end compensation circuit does not operate at temperatures above 0°C. When the temperature drops below 0°C, the circuit is activated. As the temperature decreases, the equivalent resistance decreases and the compensation voltage increases.

The increase in compensation voltage decreases the capacity of the varactor in the oscillator, increasing the output frequency of the ICOM.

The hot end compensation circuit does not operate at temperatures below +55°C. When the temperature rises above +55°C, the circuit is activated. As the temperature increases, the equivalent resistance decreases and the compensation voltage decreases. The decrease in compensation voltage increases the capacity of the varactor, decreasing the output frequency of the ICOM.

SERVICE NOTE: Proper ICOM operation is dependent on the closely-controlled input voltages from the 10-Volt regulator. Should all of the ICOMs shift off frequency, check the 10-Volt regulator module.

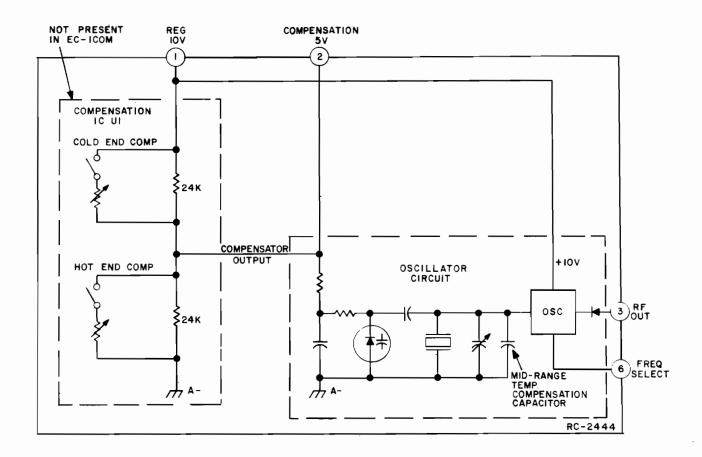


Figure 3 - Equivalent ICOM Circuit

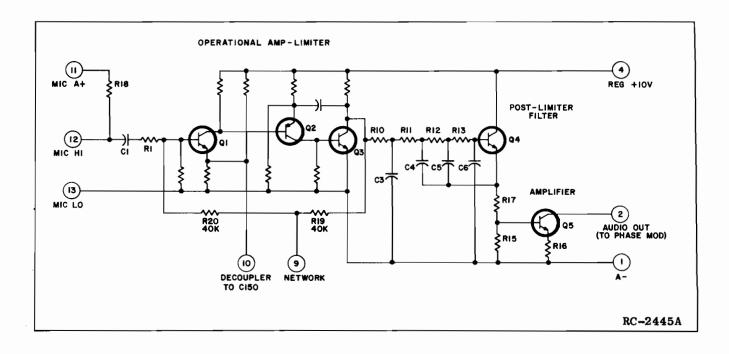


Figure 4 - Simplified Audio IC

AUDIO IC

The transmitter audio circuitry is contained in audio IC U101. A simplified drawing of the audio IC is shown in Figure 4.

Audio from the microphone at pin 12 is coupled through pre-emphasis capacitor C1 to the base of Q1 in the operational amplifier-limiter circuit. Collector voltage for the transistorized microphone pre-amplifier is supplied from pin 11 through microphone collector load resistor R18 to pin 12.

The operational amplifier-limiter circuit consists of Q1, Q2 and Q3. Q3 provides limiting at high signal levels. The gain of the operational amplifier circuit is fixed by negative feedback through R19, R20 and the resistance in the network (Pin 9).

The output of Q3 is coupled through a de-emphasis network (R10 and C3) to an active post-limiter filter consisting of C4, C5, C6, R11, R12, R13, R15, R17 and Q4.

Following the post-limiter filter is class A amplifier Q5. The output of Q5 is coupled through MOD ADJUST potentiometer R104 and resistor R125 to the phase modulator.

SERVICE NOTE: If the DC voltages to the Audio IC are correct and no audio output can be obtained, replace Ul01.

For radios equipped with Channel Guard, tone from the encoder is applied to the phase modulator through CHANNEL GUARD MOD ADJUST potentiometer R105, and resistor R127. Instructions for setting R105 are contained in the modulation adjustment section of the Transmitter Alignment Procedure.

BUFFER, PHASE MODULATORS & AMPLIFIERS

The output at pin 3 of the selected ICOM is coupled through buffer-amplifier Q101 to the modulator stage. The phase modulator is varactor (voltage-variable capacitor) CV103 in series with tunable coil T103. This network appears as a series-resonant circuit to the RF output of the oscillator. An audio signal applied to the modulator circuit through blocking capacitor C107 varies the bias of CV103, resulting in a phase modulated output. A voltage divider network (R110 and R111) provides the proper bias for varactor CV103.

The output of the modulator is coupled through blocking capacitor C150 to the base of Class A amplifier Q104. The output of the modulator is metered through C123, R128 and CR104, and is applied to the base of buffer Q105. Diodes CR105 and CR106 remove any amplitude modulation in the modulator output.

BUFFER, MULTIPLIERS & AMPLIFIER

Buffer Q105 is saturated when no RF signal is present. Applying an RF signal to Q105 provides a sawtooth waveform at its collector to drive the class C tripler, Q106. The tripler stage is metered through R138. The output of Q106 is coupled through tuned circuits T104 and T105 to the base of doubler Q107. The doubler stage is metered through R141.

The output of Q107 is coupled through tuned circuits T106 and T107 to the base of second doubler Q108. Q108 is metered through R146.

The output of Q108 is coupled through three tuned circuits (T108, T109 and T110) to the base of amplifier Q109.

Q109 is a Class C amplifier, and is metered through R148. The amplifier collector circuit consists of T111, C154, C155, T112 and C157, and matches the amplifier output to the input of the power amplifier assembly.

POWER AMPLIFIER

The PA assembly uses seven RF power transistors and seven transistors in the Power Control circuitry to provide rated power output. The broadband PA has no adjustments other than Power Control potentiometer R226.

Supply voltage for the PA is connected through power leads from the system board to feedthrough capacitors C297 and C298 on the bottom of the PA assembly. C297, C298, C299, L295 and L296 prevent RF from getting on the power leads. Diode CR295 will cause the main fuse in the fuse assembly to blow if the polarity of the power leads is reversed, providing reverse voltage protection for the radio.

Centralized metering jack J205 is provided for use with GE Test Set Model 4EX3All or Test Kit 4EX8Kl2. The Test Set meters the Tripler drive (exciter output), Ampl-2 input, Driver and PA current.

TRIPLER & RF AMPLIFIERS

The exciter output is coupled through an RF cable to PA input jack J201. The 50-ohm RF input is coupled through a matching network (C206 and W209) to the base of the broadband tripler stage, Q201.

Part of the RF input is rectified by CR201 and is used to activate the Power Control circuit. Another portion of the rectified RF is applied to J205 for metering the tripler drive.

The output of Q201 is coupled through a 20-ohm collector matching network (C212, C213, C4219 and L203) to the input of a high-pass filter consisting of C217 through C225, and W210 through W213.

Following the high-pass filter is a low-pass filter consisting of W214 through W219, C226 through C230 (and C4214 through C4217 in the 406-420 MHz band). The two filter sections combine to act as a bandpass filter providing a minimum of 60 dB rejection below 300 megahertz and 30 dB rejection above 600 megahertz.

In 450 to 512 megahertz transmitters, the filter output is coupled through a matching network (C231, C232, C233 and W220) to the base of Class C amplifier Q207. Collector voltage to Q207 is coupled through collector stabilizing network L220, R216, L219 and C234. The output of Q207 is coupled through a matching network (W221, C236, C237 and W222) to the base of the second Class C amplifier Q202. Drive to Q202 is metered at J205 (Ampl-2 Input) through metering network C238, CR202, C239 and R205.

In 406 to 420 megahertz transmitters, Q207 and its associated circuitry is removed, and the filter output is coupled through C285 to the base of second amplifier Q202.

Collector voltage for Q202 is coupled through stabilizing network L206, R206, L205 and C240. Matching network W223, C241, C242, C243 and W224 matches the output of Q202 to the base of third amplifier Q203.

Collector voltage for Q203 is applied through stabilizing network R207, L209, and C246.

The output of Q203 is coupled through a matching network (W225, C247, C248, C249 and W226) to the base of Class C driver Q204. Collector voltage for Q204 is applied through collector stabilizing network C201, L211 and C267.

Collector current for Q204 is metered across tapped manganin resistor R214 at J205 (Driver Current). The reading is taken on the one-Volt scale with the High Sensitivity button pressed, and read as 10 amperes full scale.

Following Q204 is a matching network (W227 and C253) that matches the driver output to the 50-ohm impedance of power divider network W228 and R209.

The power amplifier stages consist of two identical paralleled Class C PA circuits (Q205 and Q206). One output of the power divider network is applied to the base of Q205 through matching network W229 and C268

Supply voltage for Q205 is coupled through collector stabilizing network L213, R210, L214 and C255. The output of Q205 is coupled through a matching network (W231 and C258) and added to the output of Q206 in power combiner network R212 and W233. The combined collector current for Q205 and Q206 is metered across tapped manganin resistor R213 at J205 (PA Current). The reading is taken on the one-Volt scale with the High Sensitivity button pressed, and read as 10 amperes full scale.

The PA output is coupled through a low-pass filter to the antenna through antenna switch K201. Capacitors C214, C270 through C4218 provide DC ground isolation for \pm ground operation.

- WARNING -

The stud mount RF Power Transistors used in the transmitter contain Beryllium Oxide, a TOXIC substance. If the ceramic, or other encapsulation is opened, crushed, broken or abraded, the dust may be hazardous if inhaled. Use care in replacing transistors of this type.

POWER CONTROL CIRCUIT

When the transmitter is keyed, rectified RF from CR201 is applied to the base of switch Q208, turning it on. Turning on Q208 turns on voltage regulator Q210, supplying a constant voltage to Power Adjust potentiometer R226.

Q212, Q213 and Q215 operate as an amplifier chain to supply voltage to the collector of Q202 (Ampl-2). The setting of R226 determines the voltage applied to the base of Q212. The higher the voltage at the base of Q212, the harder the amplifiers conduct, supplying more collector voltage to Q202. The lower the voltage at the base of Q212, the less collector voltage is supplied to Q202. Reducing the supply voltage to Q202 reduces the drive to Q203 and Q204, thereby reducing the power output of the PA. The power output can be adjusted by R226 from approximately 12 to 40 Watts.

Temperature protection is provided by Q209, Q211 and thermistor RT201 which is mounted in the PA heatsink. Under normal operating conditions, the circuit is inactive (Q209 is on and Q211 is off). When the heatsink temperature reaches approximately 100°C, the resistance of RT201 decreases. This increases the base voltage applied to Q209, turning it off. Turning off Q209 allows Q211 to turn on, decreasing the voltage at Power Adjust potentiometer R226. This reduces the base voltage to Q212 which causes Q213 and Q215 to conduct less, reducing the collector voltage to Q202 (Ampl-2). This reduces the transmitter

output power, keeping the heatsink at a maximum of approximately 100°C. When the heatsink temperature decreases below 100°C, the temperature control circuit turns off, allowing the normal transmitter power output.

CARRIER CONTROL TIMER

The Carrier Control Timer option shuts off the transmitter on each transmission after a one-minute timing cycle, and alerts the operator that the transmitter is off by means of an alarm tone in the speaker. The transmitter can be turned on again by releasing and rekeying the push-to-talk switch on the microphone.

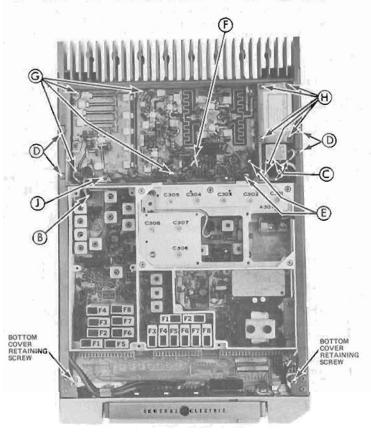
The timing cycle (transmitter keyed time) is normally set at the factory for a duration of one minute. A potentiometer permits the timing cycle to be adjusted from approximately 15 second to 3 minutes.

MAINTENANCE

DISASSEMBLY

To service the transmitter from the top:

1. Pull the locking handle down, then pry



up the cover at the front notch and lift off the cover.

To service the transmitter from the bottom:

- Pull the locking handle down and pull the radio out of the mounting frame.
- Remove the top cover, then loosen the two bottom cover retaining screws and remove the bottom cover (see Figure 5).
- 3. To gain access to the bottom of the exciter board, remove the six screws
 (A) holding the exciter board and its bottom cover to the module mounting frame, and remove the bottom cover.

To remove the exciter board from the radio:

- 1. Unplug the exciter/PA cable B
- Remove the six screws (A) holding the exciter board and its bottom cover to the module mounting frame (see Figure 6).
- Press straight down on the plug-in exciter from the top to avoid bending the pins when unplugging the board from the system board jack.

To remove the PA assembly:

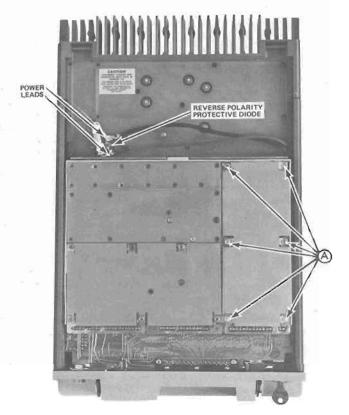


Figure 5 - Disassembly Procedure Top View

Figure 6 - Disassembly Procedure Bottom View

 Remove the four side-rail screws D, and unsolder the power cables from the bottom of the PA assembly if desired.

To remove the PA board:

- Remove the PA top cover and unplug the exciter/PA cable (B).
- 2. Unsolder the two feedthrough coils (E) and the thermistor leads (F) .
- Remove the PA transistor hold-down nuts and spring washers on the bottom of the PA assembly.
- 4. Remove the four PA board mounding screws G, the five screws in the filter casting H, and the retaining screw in Q215 J, and lift the board out.

PA TRANSISTOR REPLACEMENT

- WARNING ·

The stud mounted RF Power Transistors used in the transmitter contain Beryllium Oxide, a TOXIC substance. If the ceramic or other encapsulation is opened, crushed, broken or abraded, the dust may be hazardous if inhaled. Use care in replacing transistors of this type.

To replace the PA RF transistors:

- Unsolder one lead at a time with a 50-Watt soldering iron. Use a scribe to hold the lead away from the printed circuit board until the solder cools.
- 2. Turn the transmitter over.
- 3. Hold the body of the transistor to prevent it from turning. Remove the transistor hold-down nut and spring washer through the hole in the heatsink with an 11/32-inch nut-driver. Lift out the transistor, and remove the old solder

- from the printed circuit board with a de-soldering tool such as a SOLDA PULLT®. Special care should be taken to prevent damage to the printed circuit board runs because part of the matching network is included in the base and collector runs.
- 4. Trim the new transistor leads (if required) to the lead length of the removed transistor. Cut the collector lead at a 45° angle for future identification (see Figure 7). The letter "C" on the top of the transistor also indicates the collector.
- 5. Applying a coating of silicon grease around the transistor mounting surface, and place the transistor in the mounting hole. Align the leads as shown in the Outline Diagram. Then hold the body of the transistor and replace the holding-down nut and spring-washer, using moderate torque (8 inch-pounds). A torque wrench must be used for this adjustment since transistor damage can result if too little or too much torque is used.
- 6. Make sure that the transistor leads are formed as shown in Figure 8 so that the leads can be soldered to the printed circuit pattern, starting from the inner edge of the mounting hole.
- 7. Solder the leads to the printed circuit pattern. Start at the inner edge of mounting hole and solder the remaining length of transistor lead to the board. Use care not to use excessive heat that causes the printed wire board runs to lift up from the board. Check for shorts and solder bridges before applying power.

- CAUTION -

Failure to solder the transistor leads as directed may result in the generation of RF loops that could damage the transistor or may cause low power output.

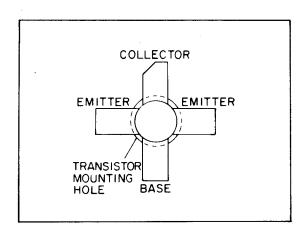


Figure 7 - Lead Identification

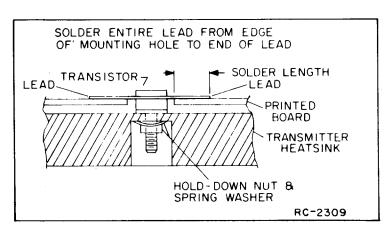


Figure 8 - Lead Forming

MODULATION LEVEL ADJUSTMENT

The MOD ADJUST (R104) was adjusted to the proper setting before shipment and should not normally require readjustment. This setting permits approximately 75% modulation for the average voice level. The audio peaks which would cause overmodulation are clipped by the modulation limiter. The limiter, in conjunction with the de-emphasis network, instantaneously limits the slope of the audio wave to the modulator, thereby preventing overmodulation while preserving intelligibility.

TEST EQUIPMENT

- 1. An audio oscillator (GE Model 4EX6Al0)
- 2. A frequency modulation monitor
- 3. An output meter or a VTVM
- 4. GE Test Set Model 4EX3All or 4EX8Kl2

PROCEDURE

- 1. Connect the audio oscillator and the meter across audio input terminals J10 (Green-Hi) and J11 (Black-Lo) on GE Test Set, and connect red Test Set plug to the System red metering plug. If not using GE Test Set, connect audio oscillator and meter across P902-6 (Mike High) through a 0.5 microfarad (or larger) DC blocking capacitor, and P902-5 (Mike-Low) on the System Board.
- 2. Adjust the audio oscillator for 1-Volt RMS at 1000 Hz.
- 3. For transmitters without Channel Guard, set MOD ADJUST R104 for a 4.5-kHz swing with the deviation polarity which gives the highest reading as indicated on the frequency modulation monitor.
- 4. For transmitters with Channel Guard, set Channel Guard MOD ADJUST R105 for zero tone deviation. Next, with the 1-Volt signal at 1000 Hz applied, set MOD ADJUST R104 for 3.75 kHz deviation. Then remove the signal from the audio oscillator and set Channel Guard MOD ADJUST R105 for 0.75 kHz tone deviation.
- 5. For multi-frequency transmitters, set the deviation as described in Steps 3 or 4 on the channel producing the largest amount of deviation.

PA POWER INPUT

For FCC purposes, the PA power input can be determined by measuring the PA supply voltage and PA current, and using the following formula:

where:

P_i is the power input in Watts,

PA voltage is measured with Test Set Model 4EX3All in Position G on the 15-Volt range (read as 15 Volts full scale), and with the polarity switch in the (-) position. With Test Set Model 4EX8K12, use the B+ position and the 1-Volt range (read as 15 Volts full scale), with the HIGH SENSITIVITY button pressed and the polarity switch in the (-) position.

PA current is measured with the Test Set in Position G in the Test 1 position, and with the HIGH SENSITIVITY button pressed (10 amperes full scale).

Example:

 $P_i = 12.6 \text{ Volts x } 3.4 \text{ amperes} = 43 \text{ Watts}$

ICOM FREQUENCY ADJUSTMENT

First, check the frequency to determine if any adjustment is required. The frequency should be set with a frequency meter or counter with an absolute accuracy that is 5 to 10 times better than the tolerance to be maintained, and with the entire radio as near as possible to an ambient temperature of 26.5°C (79.8°F).

MASTR II ICOMs should be reset only when the frequency shows deviation in excess of the following limits:

- A. ± 0.5 PPM, when the radio is at 26.5°C (79.8°F).
- B. ± 2 PPM at any other temperature within the range of -5°C to +55°C (+23°F to +131°F).
- C. The specification limit (± 2 PPM or ± 5 PPM) at any temperature within the ranges of -40° C to -5° C (-40° F to $+23^{\circ}$ F) or $+55^{\circ}$ C to $+70^{\circ}$ C ($+131^{\circ}$ F to $+158^{\circ}$ F).
- If an adjustment is required, pry up the cover on the top of the ICOM to expose the trimmer, and use one of the following procedures:
- If the radio is at an ambient temperature of 26.5°C (79.8°F), set the oscillator for the correct operating frequency.
- If the radio is not at an ambient temperature of 26.5°C, setting errors can be minimized as follows:
 - 1. Maintain the radio at 26.5°C (±5°C) and set the oscillator to desired frequency, or-

A. To hold the setting error to ±0.6 PPM (which is considered reasonable for 5 PPM ICOMS):

- 2. Maintain the radio at 26.5° C ($\pm10^{\circ}$ C) and offset the oscillator, as a function of actual temperature, by the amount shown in Figure 9.
- B. To hold setting error to ± 0.35 PPM (which is considered reasonable for 2 PPM ICOMs): Maintain unit at 26.5° C ($\pm 5^{\circ}$ C) and offset the oscillator as a function of actual temperature, by the amount shown in Figure 9.

For example: Assume the ambient temperature of the radio is $18.5^{\circ}C$ ($65.4^{\circ}F$). At that temperature, the curve shows a correction factor of 0.3 PPM. (At 406 MHz, 1 PPM is 406 Hz. At 512 MHz, 1 PPM is 512 Hz).

With an operating frequency of 450 MHz, set the oscillator for a reading of 135 Hz 0.3 x 450 Hz) higher than the licensed operating frequency. If a negative correction actor is obtained (at temperatures above 26.5°C), set the oscillator for the indicated PM lower than the licensed operating frequency.

DEGREES FAHRENHEIT

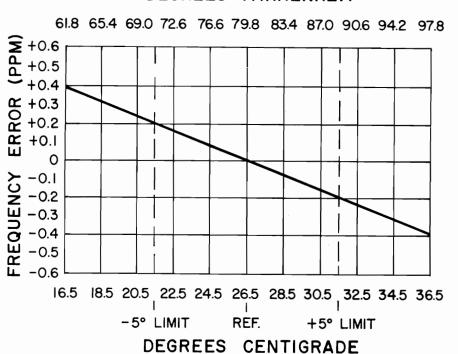
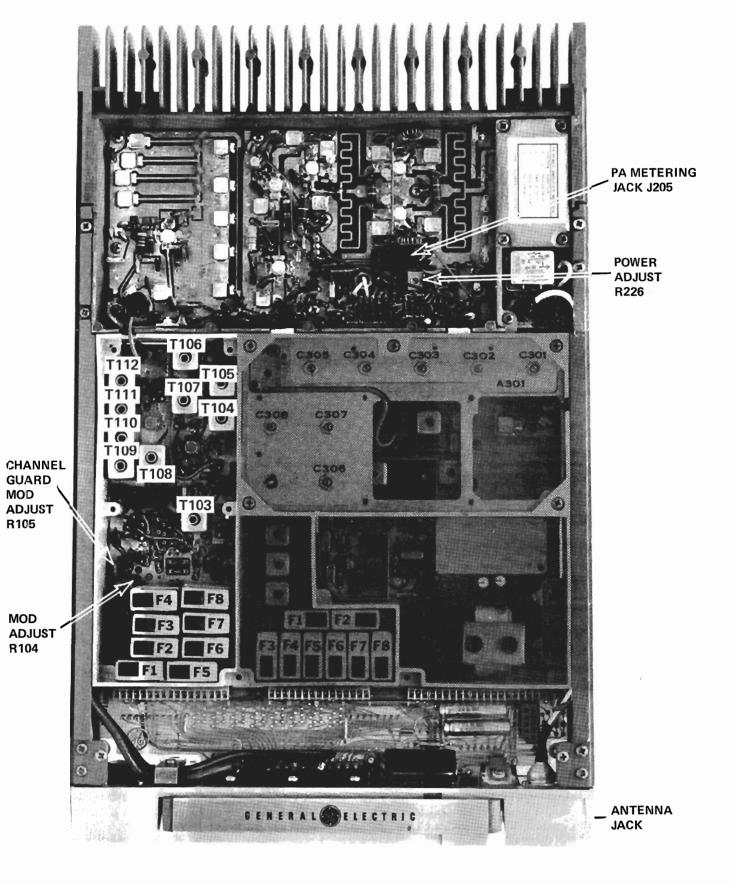


Figure 9 - Frequency Characteris ics Vs. Temperature

RC-2453



TRANSMITTER ALIGNMENT

EQUIPMENT REQUIRED

- GE Test Set Model 4EX3All or Test Kit 4EX8Kl2.
- 2. A 50-ohm wattmeter connected to antenna jack J906.

3. A frequency counter.

- PRELIMINARY CHECKS AND ADJUSTMENTS
- 1. Place ICOMs on Exciter Board (crystal frequency = operating frequency : 36).
- 2. For a large change in frequency or badly mis-aligned transmitter, pre-set the slugs in T104 and T105 to the bottom of the coil form.

 Pre-set all of the other slugs to the top of the coil form.

The tuning frequency for multi-frequency transmitters is determined by the operating frequency and the frequency spread between transmitters. Refer to the table below for maximum frequency spread.

3. For multi-frequency transmitters with a frequency spread less than that specified in column (1) tune the transmitters to the lowest frequency. For a frequency spread exceeding the limits specified in column (1) tune the transmitters using a center frequency tune up ICOM. Except the maximum frequency spread can be extended to the limits specified in column (3) with 1 dB degradation.

For tuning L101, L102, and L103, always tune L101, L102, and L103 on the lowest frequency.

Multi-frequency Transmitter Tuning

Transmitter	MAXIMUM FREQUENCY SPREAD						
Frequency Range	(1) Without center tuning	With center tuning	With center tuning (1 dB degradation)				
406-420 MHz 450-470 MHz 470-494 MHz 494-512 MHz	2.75 MHz 2.75 MHz 2.90 MHz 3.00 MHz	5.50 MHz 5.50 MHz 5.80 MHz 6.00 MHz	6.00 MHz 9.00 MHz 9.50 MHz 9.75 MHz				

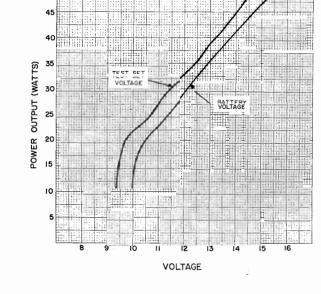
- 4. Connect the red plug on the GE Test Set to the System Board metering jack, and the black plug to the Exciter metering jack. Set the polarity to +, and set the range to the Test 1 position (1-Volt position for 4EXSK12) for all adjustments.

 NOTE: With the Test Set connected to the PA metering jack, the voltage reading at position "F" with the HIGH SENSITIVITY button pressed may be converted to driver collector current by reading the current as 10 amperes full scale. The voltage reading at position "G" with the HIGH SENSITIVITY button pressed may be converted to PA collector current by reading the current as 10 amperes full scale.
- 5. All adjustments are made with the transmitter keyed. Unkey the transmitter between steps to avoid unnecessary heating.

STEP	METER POSITION	TUNING CONTROL	METER READING	PROCEDURE
1.	B (MOD-1)	Т103	See Procedure	Tune T103 for the maximum meter reading on the lowest frequency. After tuning T103 for maximum, turn the slug 1/8 of a turn clockwise(increasing inductance
2.	(MULT-1)	T104	Minimum	Tune T104 for a dip in meter reading.
3.	D (MULT-2)	T105, T104 & T106	See Procedure	Tune T105 for maximum meter reading and re-adjust T104 for maximum meter reading. Then tune T106 for a dip in meter reading.
4.	F (MULT-3)	T107, T106, T108 & T109	See Procedure	Tune T107 for maximum meter reading and re-adjust T106 for maximum meter reading. Then tune T108 for a dip in meter reading and T109 for maximum meter reading
5.	G (AMPL-1)	T110, T108 & T109	Maximum	Tune T110 for maximum meter reading, and then re-adjust T108 and T109 for maximum meter reading.
6.	D (AMPL-1 DRIVE on PA)	T111 & T112	Maximum	Move the black metering plug to the Power Amplifier metering jack and tune Tll1 and then Tll2 for maximum meter reading. Then alternately tune Tll1 and Tll2 for maximum meter reading.
7.	G (AMPL-1)	T108, T109 & T110	Maximum	Move the black metering plug back to the exciter metering jack and re-adjust T108, T109 and T110 for maximum meter reading.
8.	D (AMPL-1 DRIVE on PA)	T111 & T112	Maximum	Move the black metering plug back to the Power Amplific metering jack and re-adjust Tl11 and Tl12 for maximum meter reading.
9.		R226		With the battery voltage at 13.6 Volts or the PA collector voltage at 130 Volts, set Power Adjust potentioneter R226 on the PA board for the desired power output (from 12 to 40 Watts). If the battery voltage is not at 13.6 Volts or the collector voltage at 13.0 Volts and full rated output is desired (40,38 or 35 Watts at 13.6 Volts), set R226 for the output power according to the battery voltage collector voltage shown in Figures 10, 11 or 12. NOTE The PA collector voltage is measured as described in the PA POWER INPUT section.



10.	D (MULT-2)	T105	See Procedure	Move the black metering plug to the exciter metering jack and re-adjust T105 for equal drive on the highest and lowest frequency.
11.	G (AMPL-1)	T110 & T108	Maximum	Re-adjust T110 and then T108 for maximum meter reading on the lowest frequency.



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Figure 11 - 38-Watt Power Output Setting Chart

VOLTAGE

Figure 10 - 40-Watt Power Output Setting Chart

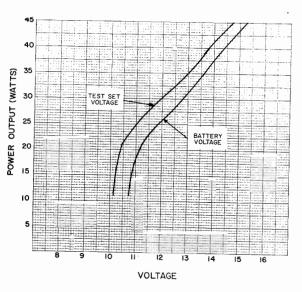


Figure 12 - 35-Watt Power Output Setting Chart

ALIGNMENT PROCEDURE

406-512 MHz, 40-WATT TRANSMITTER

Issue 2

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TEST PROCEDURES

These Test Procedures are designed to assist you in servicing a transmitter that is operating-but not properly. Problems encountered could be low power output. tone and voice deviation. defective audio sensitivity, and modulator adjust control set too high. Once a defect is pin-pointed,

refer to the "Service Check" and the additional corrective measures included in the Transmitter Troubleshooting Procedure. Before starting with the Transmitter Test Procedures, be sure the transmitter is tuned and aligned to the proper operating frequency.

CAUTION -

Before bench testing the MASTR II Mobile Radio, be sure of the output voltage characteristics of your bench power supply.

To protect the transmitter power output transistors from possible instant destruction, the following input voltages must not be exceeded:

> Transmitter unkeyed: 20 Volts Transmitter keyed (50 ohm resistive load): 18 Volts Transmitter keyed (no load or non-resistive load): 15.5 Volts

These voltages are specified at the normal vehicle battery terminals of the radio and take the voltage drop of standard cables into account. The voltage limits shown for a non-optimum load is for "worst case" conditions. For antenna mismatches likely to be encountered in practice, the actual limit will approach the 18 Volt figure.

Routine transmitter tests should be performed at EIA Standard Test Voltages (13.6 VDC for loads of 6 to 16 amperes: 13.4 VDC for loads of 16 to 36 amperes). Input voltages must not exceed the limits shown, even for transient peaks of short duration.

Many commonly used bench power supplies cannot meet these requirements for load regulation and transient voltage suppression. Bench supplies which employ "brute force" regulation and filtering (such as Lapp Model 73) may be usable when operated in parallel with a 12-Volt automotive storage battery.

TEST EQUIPMENT REQUIRED

for test hookup as shown:

1. Wattmeter similar to:

Bird # 43 Jones # 711N Triplett # 850 Heath #IM-21

GE Model 4EX6Al0

2. VTVM similar to: 3. Audio Generator similar to: 4. Deviation Meter (with a .75 kHz scale) similar to: Measurements # 720

5. Multimeter similar to:

GE TEST SET MODEL 4EX3A11. MODEL 4EX8K12 or 20,000 ohms-per-Volt voltmeter

POWER MEASUREMENT

TEST PROCEDURE

- 1. Connect transmitter output from the antenna jack to the wattmeter through a 50-ohm coaxial cable. Make sure the wattmeter is terminated into a 50-ohm load.
- 2. Key the transmitter and check the wattmeter for the desired power output.

SERVICE CHECK

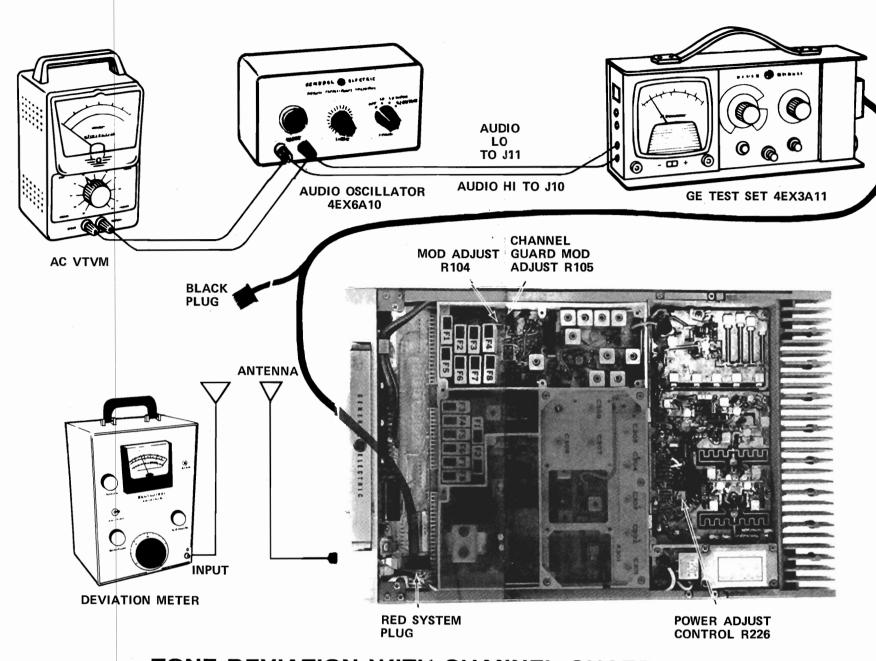
Check the setting of the Power Adjust Control (R226).

Refer to the QUICK CHECKS on the Transmitter Troubleshooting Procedure.

VOICE DEVIATION. SYMMETRY AND AUDIO SENSITIVITY

TEST PROCEDURE

- 1. Connect the test equipment to the transmitter as shown.
- 2. In radios with Channel Guard, set Channel Guard Mod Adjust R105 for zero tone deviation.
- 3. Set the Audio generator output to 1.0 VOLTS RMS and frequency to 1 kHz.
- 4. Key the transmitter and adjust Deviation Meter to carrier frequency.
- 5. Deviation reading should be ±4.5 kHz in radios without Channel Guard, and ±3.75 kHz in radios with Channel Guard.
- 6. If necessary, adjust MOD ADJUST control R104 for the proper deviation on plus (+) or minus (-) deviation, whichever is greater.
- NOTES: -- MASTR II transmitters are adjusted for 4.5 kHz deviation at the factory. The factory adjustment will prevent the transmitter from deviating more than 5.0 kHz under the worst conditions of frequency, voltage and temperature.
- 7. If the deviation reading plus (+) or minus (-) differs by more than 0.5 kHz. recheck Steps 1 and 2 as shown in the Transmitter Alignment Chart.
- 8. Check Audio Sensitivity by reducing generator output until deviation falls to 3.0 kHz for radios without Channel Guard, or 2.25 kHz for radios with Channel Guard. Voltage should be LESS than 120 millivolts. If not, refer to the Transmitter Troubleshooting Procedure.



TONE DEVIATION WITH CHANNEL GUARD

TEST PROCEDURE

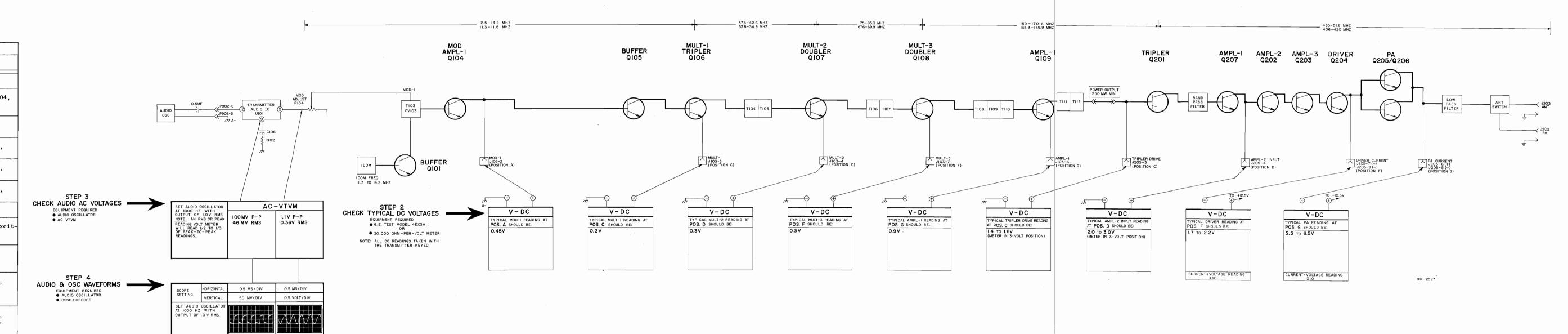
- 1. Set up the Deviation Meter and monitor the output of the transmitter.
- 2. Remove the 1000 Hz signal from the audio generator.
- 3. Key the transmitter and check for 0.75 kHz deviation. If the reading is low or high, adjust Channel Guard MOD ADJUST R105 for a reading of 0.75 kHz.

NOTES:

- 1. On units supplied with Channel Guard, the Phase Modulator Tuning should be adjusted carefully to insure proper performance. (Refer to Step 1 in the Transmitter Alignment Chart).
- 2. The Tone Deviation Test Procedures should be repeated every time the Tone Frequency is changed.

STEP I - QUICK CHECKS

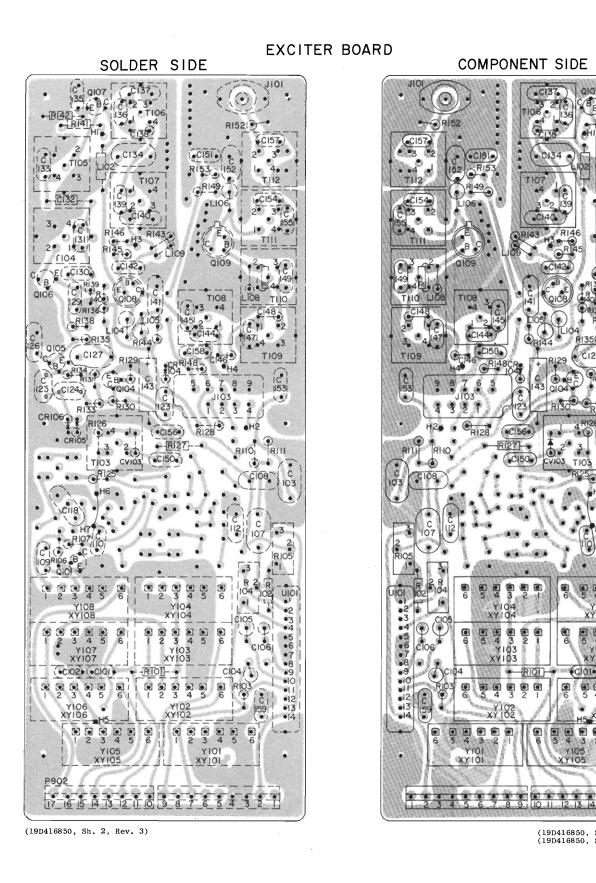
METER		PROBABLE DEF	ECTIVE STAGE
POSITION GE TEST SET	HIGH METER READING	LOW METER READING	ZERO METER READING
	EXCITER	+	
B (MOD-1)	Q102, 10- Volt Regulator	T103, CV103 C104	T103, CV103, CR104, Q104
C (MULT-1)	Q105, Q106 T104	Q105, Q106	Q105, Q106, T104
D (MULT-2)	Q107, T106	T104, T104, Q107	T104, T105, Q107, T106
F (MULT-3)	Q108, T108	T106, T107, Q108	T106, T107, Q108, T108
G (AMPL-1)	Q109, C157	T108, T109, T110, Q109	T108, T109, T110, Q109, L106
	POWER AMPLIFIER		
"C" (TRIPLER DRIVE)		Low Output from Exciter	No output from Excit er CR201
"D" (AMPL-2 INPUT)	Q207	Q207	Q207, Q201
"F" (DRIVER CURRENT)	Q204	Q204, Low Output from Q201, Q207, Q202, Q203	Q203, Q202, Q207, Q201. Check Pos. C & D
"G" (PA CURRENT)	Q205, Q206	Q201, Q207, Q202, Q203, Q204, Q205, Q206	Q206, Q205, Q204, Q203, Q202, Q207, Q201, Q215



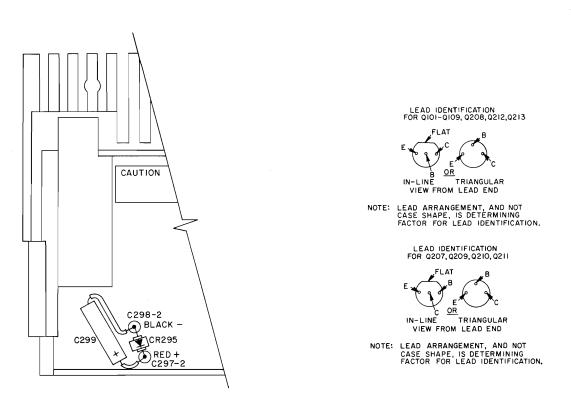
TROUBLESHOOTING PROCEDURE

406-512 MHz, 40-WATT TRANSMITTER

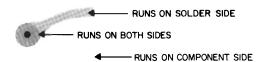
11



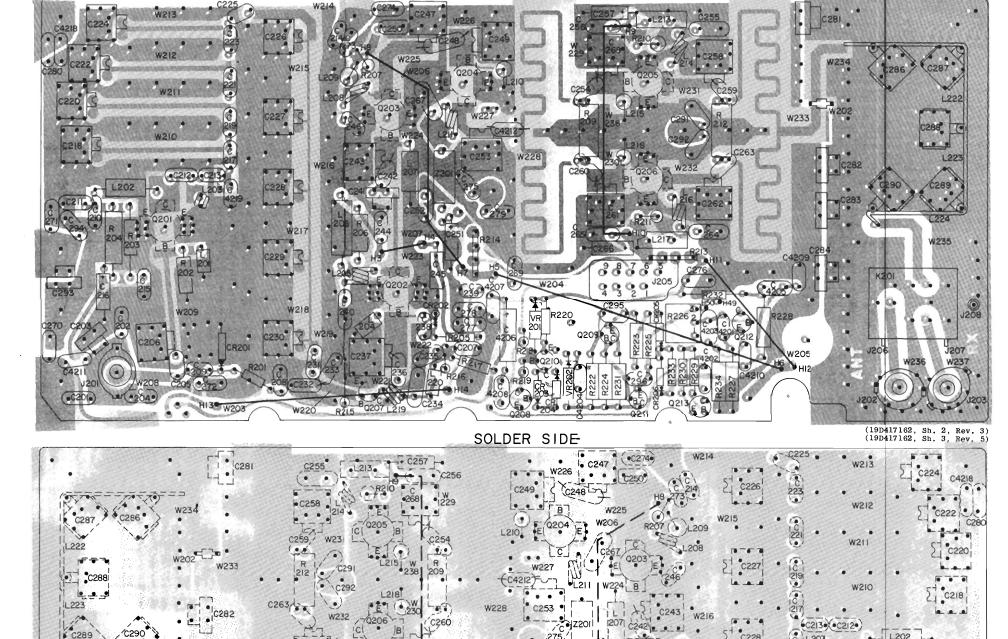
PA ASSEMBLY TOP VIEW B Q204 E C E E C E B E C B Q206 B E C C Q201 C Q201 F B E C RT201 HI5 HI6 C Q215 C Q215



(19R622078, Rev. 3)



PA BOARD COMPONENT SIDE



OUTLINE DIAGRAM

406—512 MHz, 40-WATT TRANSMITTER

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Issue 2

(19D417162, Sh. 2, Rev. 3)

PRODUCTION CHANGES

Changes in the equipment to improve performance or to simplify circuits are identified by a "Revision Letter", which is stamped after the model number of the unit. The revision stamped on the unit includes all previous revisions. Refer to the Parts List for descriptions of parts affected by these revisions.

- REV. A: Exciter Board 19D416859G5, G7, To improve operation.

 Deleted C136L. Changed C136H, C137, C144L, C145, C146, CV103. Added C137L, C145L, C146L, CV103L, L108, R152 and R153.
- REV. B: To improve drive to modulator. Changed Q101 and R106.
- REV. C: To increase power output and decrease transmitter noise. Changed Q109, R149 and C109. Deleted R153, C155L and C157L. Added C161L and C162L.
- REV. A: Exciter Board 19D416859G6, G8, To improve drive to modulator. Changed Q101 and R106.
- REV. B: To increase power output and reduce transmitter noise.
 Changed Q109, R149, and C109. Deleted C155H and C157H.
 Added C161H and C162H.

DA	DTC	1	IST	

LBI-4609A

406-420 MHz, 450-512 MHz EXCITER BOARD 19D416859G5-G8

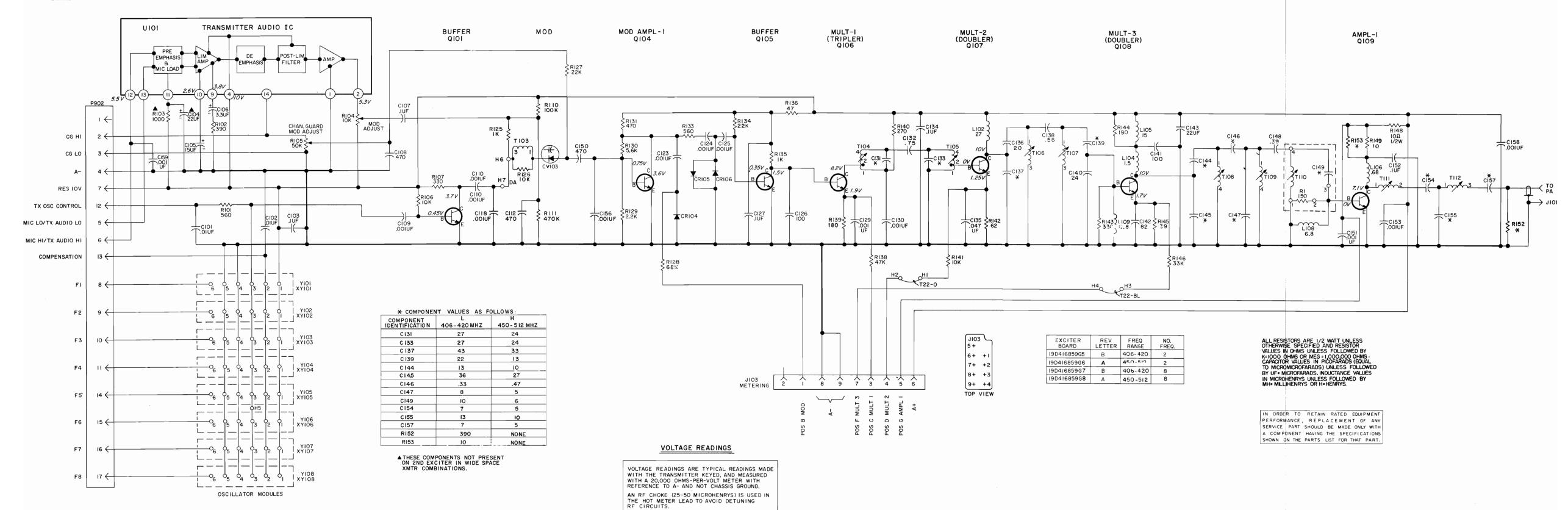
SYMBOL	GE PART NO.	DESCRIPTION
		19D416859G5 2 FREQ 406-420 MHz (L)
		19D416859G6 2 FREQ 450-512 MHz (H) 19D416859G7 8 FREQ 406-420 MHz (L) 19D416859G8 8 FREQ 450-512 MHz (H)
C101 and C102	19A116080P1	Polyester: 0.01 μf ±20%, 50 VDCW.
C103	19A116080P107	Polyester: 0.1 µf ±10%, 50 VDCW.
C104	5496267P10	Tantalum: 22 μf ±20%, 15 VDCW; sim to Sprague Type 150D.
C105	5496267P14	Tantalum: 15 µf ±20%, 20 VDCW; sim to Sprague Type 150D.
C106	5496267P9	Tantalum: 3.3 µf ±20%, 15 VDCW; sim to Sprague Type 150D.
C107	19A116080P107	Polyester: 0.1 µf ±10%, 50 VDCW.
C108	5494481P107	Ceramic disc: 470 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.
C109 and C110	5494481P111	Ceramic disc: 1000 pf $\pm 20\%$, 1000 VDCW; sim to RMC Type JF Discap.
C112	5494481P107	Ceramic disc: 470 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.
C118	5494481P112	Ceramic disc: 1000 pf \pm 10%, 1000 VDCW; sim to RMC Type JF Discap.
C123 thru C125	5494481P111	Ceramic disc: 1000 pf $\pm 20\%$, 1000 VDCW; sim to RMC Type JF Discap.
C126	7489162 P2 7	Silver mica: 100 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.
C127	19A116080P107	Polyester: 10 µf ±10%, 50 VDCW.
C129 and C130	5494481P111	Ceramic disc: 1000 pf $\pm 20\%$, 1000 VDCW; sim to RMC Type JF Discap.
C131L	5496219 P 249	Ceramic disc: 27 pf ±5%, 500 VDCW, temp coef -80 PPM.
С131Н	5496219P248	Ceramic disc: 24 pf ±5%, 500 VDCW, temp coef -80 PPM.
C132	5491601P118	Phenolic: 0.75 pf ±5%, 500 VDCW.
C133L	5496219P249	Ceramic disc: 27 pf $\pm 5\%$, 500 VDCW, temp coef -80 PPM.
С133Н	5496219P248	Ceramic disc: 24 pf ±5%, 500 VDCW, temp coef -80 PPM.
C134	19A116080P107	Polyester: 0.1 µf ±10%, 50 VDCW.
C135	19A116080P105	Polyester: 0.047 μf ±10%, 50 VDCW.
C136*	5496219P246	Ceramic disc: 20 pf ±5%, 500 VDCW, temp coef -80 PPM. Added to G5 and G7 by REV A.
C136L*	5496219P348	Ceramic disc: 24 pf ±5%, 500 VDCW, temp coef -150 PPM. Deleted from G5 and G7 by REV A.
C136H*	5496219P246	Ceramic disc: 20 pf ±5%, 500 VDCW, temp coef -80 PPM. Deleted from G5 and G7 by FEV A.
C137*	5496219P251	Ceramic disc: 33 pf ±5%, 500 VDCW, temp coef -80 PPM. Deleted from G5 and G7 by REV A.
C137L*	5496219P254	Ceramic disc: 43 pf $\pm 5\%$, 500 VDCW, temp coef -80 PPM. Added to G5 and G7 by REV A.
C137H*	5496219P251	Ceramic disc: 33 pf ±5%, 500 VDCW, temp coef -80 PPM. Added to G5 and G7 by REV A.
C138	5491601P115	Phenolic: 0.56 pf ±5%, 500 VDCW.
C139L	5496219P247	Ceramic disc: 22 pf ±5%, 500 VDCW, temp coef -80 PPM.
С139Н	5496219P243	Ceramic disc: 13 pf ±5%, 500 VDCW, temp coef -80 PPM.
		Ceramic disc: 24 pf ±5%, 500 VDCW, temp coef

C141		I de la companya de					GE PART NO.	DESCRIPTION
	5490008P127	Silver mica: 100 pf ±10%, 500 VDCW; sim to	J 103	19B219374G1	Connector. Includes:	R141	3R152P103K	Composition, 10 000 -b 1207
	0100001121	Electro Motive Type DM-15.		19A116651P1	Contacts. (9).	R141	3R152P620J	Composition: 10,000 ohms ±10%, 1/4 w. Composition: 62 ohms ±5%, 1/4 w.
C142	7489162P25	Silver mica: 82 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.				R143	3R152P331K	Composition: 330 ohms ±10%, 1/4 w.
C143	5496267P10	Tantalum: 22 μf ±20%, 15 VDCW; sim to Sprague	L102	19B209420P130	Coil, RF: 27.0 µh ±10%, 3.60 ohms DC res max;	R144	3R152P181K	Composition: 180 ohms ±10%, 1/4 w.
C144L*	5496219P243	Type 150D. Ceramic disc: 13 pf ±15%, 500 VDCW, temp coef			sim to Jeffers 441316-5.	R145	3R152P390K	Composition: 39 ohms $\pm 10\%$, $1/4$ w.
01112	01002101210	-80 PPM.	L104	7488079P7	Choke, RF: 1.50 μh ±10%, 0.50 ohms DC res max; sim to Jeffers 4411-10K.	R146	3R152P333K	Composition: 33,000 ohms ±10%, 1/4 w.
		In G5 and G7 earlier than REV A:	L105	7488079P18	Choke, RF: 15.0 µh ±10%, 1.20 ohms DC res max; sim to Jeffers 4421-9K.	R148	3R77P100J	Composition: 10 ohms ±5%, 1/2 w.
	5496219P244	Ceramic disc: 15 pf ±15%, 500 VDCW, temp coef -80 PPM.	L106	7488079P5	Choke, RF: 0.68 \(\mu \) \(\pm \)	R149	3R152P100K	Composition: 10 ohms ±10%, 1/4 w.
C144H	5496219P241	Ceramic disc: 10 pf ±0.25 pf, 500 VDCW, temp coef -80 PPM.	L108	19B209420P123	sim to Jeffers 4411-5K.	R152*	3R152P391K	Composition: 390 ohms ±10%, 1/4 w. Added to G5 and G7 by REV A.
C145*	5496219P249	Ceramic disc: 27 pf ±5%, 500 VDCW, temp coef -80 PPM. Deleted in G5 and G7 by REV A.	and L109	1982094209123	Coil, RF: $6.80~\mu h \pm 10\%$, $1.80~ohms$ DC res max; sim to Jeffers $4446-2$.	R153*	3R152P100K	Composition: 10 ohms ±10%, 1/4 w. Added to G5 and G7 by REV A.
C145L*	5496219 P2 52	Ceramic disc: 36 pf ±5%, 500 VDCW, temp coef -80 PPM. Added to G5 and G7 by REV A.						
C145H*	5496219P249	Ceramic disc: 27 pf ±5%, 500 VDCW, temp coef	P902		Includes:	T103	19D416843G1	Coil. Includes:
		-80 PPM. Added to G5 and G7 by REV A.		19B219594P2 19B219594P3	Contact strip: 8 pins.		5493185P12	Tuning slug.
C146*	5491601P113	Phenolic: 0.47 pf ±5%, 500 VDCW. Deleted in G5 and G7 by REV A.		19821959423	Contact strip: 9 pins.	T104	19D416843G3	Coil. Includes:
C146L*	5491601P109	Phenolic: 0.33 pf ±5%, 500 VDCW. Added to G5 and G7 by REV A.				T105	5493185P12	Tuning slug.
C146H*	5491601P113	Phenolic: 0.47 pf ±5%, 500 VDCW. Added to G5	Q101*	19A115330P1	Silicon, NPN.	1105	19D416843G2 5493185P12	Coil. Includes: Tuning slug.
011011		and G7 by REV A.			In G5, G7 of REV A and earlier: In G6, G8 of REV B and earlier:	T106	19D416843G7	Coil. Includes:
C147L	5496219P239	Ceramic disc: 8.0 pf ±0.25 pf, 500 VDCW, temp coef -80 PPM.		19A115910P1	Silicon, NPN; sim to Type 2N3904.	and T107		
С147Н	5496219P236	Ceramic disc: 5.0 pf ±0.25 pf, 500 VDCW, temp	Q104 thru	19A115330P1	Silicon, NPN.		5493185P12	Tuning slug.
C148	5491601P111	coef -80 PPM. Phenolic: 0.39 pf ±5%, 500 VDCW.	Q106			T108 and T109	19D416843G5	Coil. Includes:
C148 C149L	5496219P241	Ceramic disc: 10 pf ±0.25 pf, 500 VDCW, temp	Q107	19A115328P1	Silicon, NPN.	1109	5493185P13	Tuning slug.
		coef -80 PPM.	Q108 and Q109	19A115329P2	Silicon, NPN.	T110		COIL ASSEMBLY
С149Н	5496219P237	Ceramic disc: 6.0 pf ±0.25 pf, 500 VDCW, temp coef -80 PPM.	Q105		RESISTORS			19D416843G8
C150	5496372P365	Ceramic disc: 470 pf ±10%, 500 VDCW, temp coef -4700 PPM.	R101	3R152P561K	Composition: 560 ohms ±10%, 1/4 w.			
C151	19A116655P19	Ceramic disc: 1000 pf ±20%, 1000 VDCW; sim to	R102	3R152P391K	Composition: 390 ohms ±10%, 1/4 w.	R1	3R152P151K	Composition: 150 ohms ±10%, 1/4 w.
		RMC Type JF Discap.	R103	3R152P102K	Composition: 1000 ohms ±10%, 1/4 w.			MISCELLANEOUS
C152	19A116080P107 19A116655P19	Polyester: 0.1 µf ±10%, 50 VDCW. Ceramic disc: 1000 pf ±20%, 1000 VDCW; sim to	R104	19B209358P106	Variable, carbon film: approx 75 to 10,000 ohms ±10%, 0.25 w; sim to CTS Type X-201.		5493185P13	Tuning slug.
C153	19A110055P19	RMC Type JF Discap.	R105	19B209358P108	Variable, carbon film: approx 100 to 50,000 ohms	T111	19D416843G4	Coil. Includes:
C154L	5496219P238	Ceramic disc: 7.0 pf ±0.25 pf, 500 VDCW, temp coef -80 PPM.	R106*	3R152P103K	±10%, 0.25 w; sim to CTS Type X-201. Composition: 10.000 ohms ±10%, 1/4 w.		5493185P12	Tuning slug.
C154H	5496219P236	Ceramic disc: 5.0 pf ±0.25 pf, 500 VDCW, temp	**************************************	3R132P103R	In G5, G7 of REV A and earlier:	T112	19D416843G6	Coil. Includes:
C155L	5496219P243	coef -80 PPM. Ceramic disc: 13 pf ±5%, 500 VDCW, temp coef			In G6, G8 of REV B and earlier:		5493185P12	Tuning slug.
CISSE	3430213F243	-80 PPM.		3R152P393K	Composition: 39,000 ohms ±10%, 1/4 w.			INTEGRATED CIRCUITS
С155Н	5496219P241	Ceramic disc: 10 pf ±0.25 pf, 500 VDCW, temp coef -80 PPM.	R107 R110	3R152P331K 3R152P104K	Composition: 330 ohms ±10%, 1/4 w.	U101	19D416542G1	Audio Transmitter,
C156	5494481Pl12	Ceramic disc: 1000 pf ±10%, 1000 VDCW; sim to	R111	3R152P474K	Composition: 0.10 megohm ±10%, 1/4 w. Composition: 0.47 megohm ±10%, 1/4 w.			
C157L	5496219P238	RMC Type JF Discap. Ceramic disc: 7.0 pf ±0.25 pf, 500 VDCW, temp	R125	3R152P102K	Composition: 101000 ohms ±10%, 1/4 w.	XY101 thru		Socket. Part of Mechanical Construction. Includes:
CISTE	34302137230	coef -80 PPM.	R126	3R152P103K	Composition: $10,000$ ohms $\pm 10\%$, $1/4$ w.	XY108	19A116779P1	Contact, electrical: sim to Molex 08-54-0404.
С157Н	5496219P236	Ceramic disc: 5.0 pf ±0.25 pf, 500 VDCW, temp coef -80 PPM.	R127	3R152P223K	Composition: 22,000 ohms ±10%, 1/4 w.			Quantity (6) with each.
C158	19A116655P19	Ceramic disc: 1000 pf ±20%, 1000 VDCW; sim to	R128	3R152P683K	Composition: 69,000 ohms ±10%, 1/4 w.			
and C159		RMC Type JF Discap.	R129	3R152P222K	Composition: 2200 ohms ±10%, 1/4 w.			NOTE: When reordering specify ICOM Frequency.
		DIODES AND RECTIFIERS	R130	3R152P562K	Composition: 5600 ohms ±10%, 1/4 w.			ICOM Freq = Operating Frequency
CR104 thru	19A115250P1	Silicon.	R131 R133	3R152P471K 3R152P561K	Composition: 470 ohms ±10%, 1/4 w. Composition: 560 ohms ±10%, 1/4 w.			36
CR106	5495769P8	Silicón, capacitive: 33 pf ±20%, at 4 VDC.	R134	3R152P223K	Composition: 22,000 ohms ±10%, 1/4 w.	Y101 thru	19A129393G18	Externally compensated, ±5 PPM, 406-512 MHz.
CV103*	0.49010980	Deleted in G5 and G7 by REV A.	R135	3R152P102K	Composition: 1000 ohms $\pm 10\%$, $1/4$ w.	Y108		
CV103L*	5495769P9	Silicon, capacitive: 33 pf ±20%, at 4 VDC. Added to G5 and G7 by REV A.	R136	3R152P470K	Composition: 47 ohms ±10%, 1/4 w.	Y101 thru	19A129393G15	Externally compensated, ±2 PPM, 406-512 MHz.
CV103H*	5495769P8	Silicon, capacitive: 33 pf ±20%, at 4 VDC.	R138	3R152P473K	Composition: 47,000 ohms ±10%, 1/4 w.	¥108		
		Added to G5 and G7 by REV A.	R139	3R152P181K	Composition: 180 ohms ±10%, 1/4 w.			MECHANICAL PARTS
		JACKS AND RECEPTACLES	R140	3R152P271K	Composition: 270 ohms ±10%, 1/4 w.		19A129424G2	Can. (Used with T103-T112).
J101	19A116832P1	Receptacle, coaxial: sim to Cinch 14H11613.					4036555P1	Insulator, washer: nylon. (Used with Q108,
					:			Q109).

*COMPONENTS ADDED, DELETED OR CHANGED BY PRODUCTION CHANGES

LBI-4622

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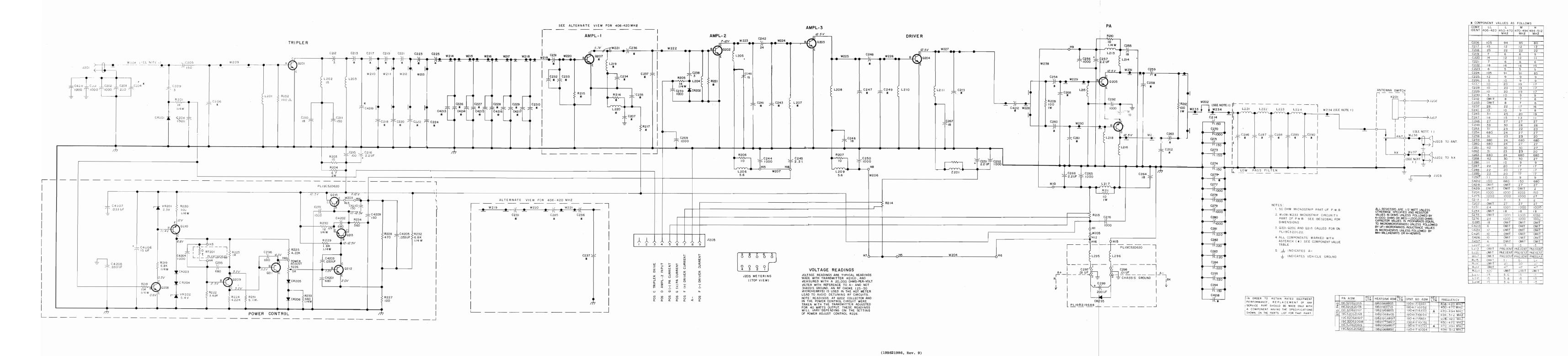
SCHEMATIC DIAGRAM

406—512 MHz, EXCITER BOARD 19D416859G5-G8

Issue 2

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(19R622018, Rev. 5)



SCHEMATIC DIAGRAM

406-512 MHz, 40-WATT POWER AMPLIFIER 19C320620G5-G8

Issue 2

PARTS LIST	
LBI-4619A	
406-420, 450-512 MHz 40 WATT POWER AMPLIFIER 19C320620G5-G8	

SYMBOL	GE PART NO.	DESCRIPTION
L295 and L296	19A129562P2	INDUCTORS
Q20	19A129283P1	Silicon, NPN.
Q201	19A116953P1	Silicon, NPN.
Q203 Q204 thru Q206	19A116953P2 19A129283P4	Silicon, NPN. Silicon, NPN.
Q215	19A116742P1	Silicon, NPN.
RT201	19A129379G1	Thermistor.
		POWER AMPLIFIER BOARD 19D417166G1 403-420 MHz (LL) 19D417166G2 450-470 MHz (L) 19D417166G3 470-494 MHz (M) 19D417166G4 494-512 MHz (H)
C201	19A116655P20	
and C202	1	sim to RMC Type JF Discap.
C203	19A116679P220K	Mica: 220 pf ±10%, 250 VDCW.
C204LL	19A116655P20 \	Ceramic disc: 1000 pf ±10%, 1000 VDCW; sim to RMC Type JF Discap.
C204L	19A116655P20	Ceramic disc: 1000 pf ±10%, 1000 VDCW; sim to RMC Type JF Discap.
C204M	19A116655P20	Ceramic disc: 1000 pf ±10%, 1000 VDCW; sim to RMC Type JF Discap.
C204H	19A116655P8	Ceramic disc: 150 pf ±10%, 1000 VDCW; sim to RMC Type JF Discap.
C205	19A116655P8	Ceramic disc: 150 pf ±10%, 1000 VDCW; sim to RMC Type JF Discap.
C206LL	19A116952P105	Silver mica: 105 pf ±2%, 250 VDCW; sim to Underwood Type JlHF.
C206L	19A116952P94	Silver mica: 94 pf ±2%, 250 VDCW; sim to Underwood Type JlHF.
C206M	19A116952P85	Silver mica: 85 pf $\pm 2\%$, 250 VDCW; sim to Underwood Type J1HF.
С206Н	19A116952P80	Silver mica: 80 pf ±2%, 250 VDCW; sim to Underwood Type JlHF.
C207	5496218P249	Ceramic disc: 27 pf ±5%, 500 VDCW, temp coef -80 PPM.
C208	19A116655P20	Ceramic disc: 1000 pf ±10%, 1000 VDCW; sim to RMC Type JF Discap.
C209	19A116656P3J0	Ceramic disc: 3 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.
C210	7489162P9	Silver mica: 18 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.
C211	19A116655P8	Ceramic disc: 150 pf ±10%, 1000 VDCW; sim to RMC Type JF Discap.
C212	19A116656P3J0	Ceramic disc: 3 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.
C213LL	19A116656P3J0	Ceramic disc: 3 pf ± 0.5 pf, 500 VDCW, temp coef 0 PPM.
C213L	19A116656P3J0	Ceramic disc: 3 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.

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/		SYMBOL	GE PART NO.	DESCRIPTION
		C213M	19A116656P3J0	Ceramic disc: 3 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.
		С213Н	5491238P12	Ceramic disc: 2 pf ±0.25 pf, 500 VDCW, temp coef ±120 PPM.
	_	C214	19A116655P8	Ceramic disc: 150 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.
		C215	19A116655P20	Ceramic disc: 1000 pf ±10%, 1000 VDCW; sim to RMC Type JF Discap.
	\forall	C216	5496267P13	Tantalum: 2.2 µf ±20%, 20 VDCW; sim to Sprague Type 150D.
	l	C217LL	19A116656P15J0	Ceramic disc: 15 pf ±5%, 500 VDCW, temp coef 0 PPM.
		C217L	19A116656P12J0	Ceramic disc: 12 pf ±5%, 500 VDCW, temp coef 0 PPM.
	l	C217M	19A116656P12J0	Ceramic disc: 12 pf ±5%, 500 VDCW, temp coef 0 PPM.
		C217H	19A116656P12J0	Ceramic disc: 12 pf ±5%, 500 VDCW, temp coef 0 PPM.
		C218LL	19A116952P25	Silver mica: 25 pf ±2%, 250 VDCW; sim to Underwood Type JlHF.
		C218L	19A116952P22	Silver mica: 22 pf ±2%, 250 VDCW; sim to Underwood Type J1HF.
		C218M	19A116952P22	Silver mica: 22 pf ±2%, 250 VDCW; sim to Underwood Type J1HF.
	l	C218H	19A116952P22	Silver mica: 22 pf ±2%, 250 VDCW; sim to
		C219LL	19A116656P7J0	Underwood Type J1HF. Ceramic disc: 7 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.
	l	C219L .	19A116656P6J0	Ceramic disc: 6 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.
	l	C219M	19Al16656P6J0	Ceramic disc: 6 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.
		С219Н	19A116656P5J0	Ceramic disc: 5 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.
	l	C220LL	19A116952P14	Silver mica: 14 pf ±0.5 pf, 250 VDCW; sim to Underwood Type J1HF.
	ļ	C220L	19A116952P12	Silver mica: 12 pf ±0.5 pf, 250 VDCW; sim to Underwood Type J1HF.
	l	C220M	19A116952P12	Silver mica: 12 pf ±0.5 pf, 250 VDCW; sim to
	l	С220Н	19A116952P11	Underwood Type J1HF. Silver mica: 11 pf ±0.5 pf, 250 VDCW; sim to Underwood Type J1HF.
	l	C221LL	19A116656P7J0	Ceramic disc: 7 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.
	l	C221L	19A116656P6J0	Ceramic disc: 6 pf ±0.5 pf, 500 VDCW, temp
	l	C221M	19A116656P6J0	Ceramic disc: 6 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.
to	ļ	C221H	19A116656P6J0	Ceramic disc: 6 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.
0		C222LL	19A116952P18	Silver mica: 18 pf ±0.5 pf, 250 VDCW; sim to Underwood Type J1HF.
0		C222L	19A116952P16	Silver mica: 16 pf ±0.5 pf, 250 VDCW; sim to Underwood Type JlHF.
D		C222M	19A116952P16	Silver mica: 16 pf ±0.5 pf, 250 VDCW; sim to Underwood Type J1HF.
		C222H	19A116952P15	Silver mica: 15 pf ±0.5 pf, 250 VDCW; sim to
		C223LL	19A116656P6J0	Ceramic disc: 6 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.
emp		C223L	19A116656P5J0	Ceramic disc: 5 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.
•	1,000,000	C223M	19A116656P5J0	Ceramic disc: 5 pf ±0.5 pf, 500 VDCW, temp. coef 0 PPM.
		С223Н	19A116656P5J0	Ceramic disc: 5 pf ±0.5 pf, 500 VDCW, temp
emp		C224LL	19A116952P105	coef 0 PPM. Silver mica: 105 pf ±2%, 250 VDCW; sim to
emp		C224L	19Al16952P91	Underwood Type J1HF. Silver mica: 91 pf ±2%, 250 VDCW; sim to
emp		C224M	19A116952P91	Underwood Type JlHF. Silver mica: 91 pf ±2%, 250 VDCW; sim to
				Underwood Type J1HF.

CRIPTION	SYMBOL	GE PART NO.	DESCRIPTION	SYMBOL	GE PART NO.	DESCRIPTION	SYMBOL	GE PART NO.	DESCRIPTION
±0.5 pf, 500 VDCW, temp	С224Н	19A116952P85	Silver mica: 85 pf ±2%, 250 VDCW; sim to Underwood Type JlHF.	C236LL	19A116656P24J0	Ceramic disc: 24 pf ±5%, 500 VDCW, temp coef	C253LL	19A116952P31	Silver mica: 31 pf ±2%, 250 VDCW; sim to Underwood Type J1HF.
±0.25 pf, 500 VDCW,	C225LL	19A116656P12J0	Ceramic disc: 12 pf ±5%, 500 VDCW, temp coef 0 PPM.	C236L	19A116655P20	Ceramic disc: 1000 pf ±10%, 1000 VDCW; sim to RMC Type JF Discap.	C253L	19A116952P23	Silver mica: 23 pf ±0.5 pf, 250 VDCW; sim to Underwood Type JlHF.
of ±20%, 1000 VDCW;	C225L	19A116656P9J0	Ceramic disc: 9 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.	C236M	19A116655P20	Ceramic disc: 1000 pf ±10%, 1000 VDCW; sim to RMC Type JF Discap.	C253M	19Al16952P22	Silver mica: 22 pf ±0.5 pf, 250 VDCW; sim to Underwood Type JlHF.
pf ±10%, 1000 VDCW;	C225M	19Al16656P9J0	Ceramic disc: 9 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.	С236Н	19A116655P20	Ceramic disc: 1000 pf ±10%, 1000 VDCW; sim to RMC Type JF Discap.	С253Н	194116952P20	Silver mica: 20 pf ±0.5 pf, 250 VDCW; sim to Underwood Type JlHF.
20%, 20 VDCW; sim to Sprague	С225Н	19A116656P9J0	Ceramic disc: 9 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.	C237LL	19A116952P28	Silver mica: 28 pf ±2%, 250 VDCW; sim to Underwood Type J1HF.	C254LL	19A116655P18	Ceramic disc: 680 pf ±10%, 1000 VDCW; sim to RMC Type JF Discap.
±5%, 500 VDCW, temp	C226LL	19A116656P5J0	Ceramic disc: 5 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.	C237L	19A116952P22	Silver mica: 22 pf ±0.5 pf, 250 VDCW; sim to Underwood Type J1HF.	C254L	19A116656P24J0	Ceramic disc: 24 pf ±5%, 500 VDCW, temp coef 0 PPM.
±5%, 500 VDCW, temp	C226L	19A116952P10	Silver mica: 10 pf ±0.5 pf, 250 VDCW; sim to Underwood Type JlHF.	C237M	19A116952P17	Silver mica: 17 pf ±0.5 pf, 250 VDCW; sim to Underwood Type JlHF.	C254M	5496218P249	Ceramic disc: 27 pf ±5%, 500 VDCW, temp coef -80 PPM.
±5%, 500 VDCW, temp	C226M	19A116952P9	Silver mica: 9 pf ±0.5 pf, 250 VDCW; sim to Underwood Type J1HF.	C237H	19A116952P16	Silver mica: 16 pf ±0.5 pf, 250 VDCW; sim to Underwood Type J1HF.	C254H	5496218P249	Ceramic disc: 27 pf ±5%, 500 VDCW, temp coef -80 PPM.
±5%, 500 VDCW, temp	С226Н	19A116952P9	Silver mica: 9 pf ±0.5 pf, 250 VDCW; sim to Underwood Type JlHF.	C238	19A116656P3J0	Ceramic disc: 3 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.	C255	7489162P9	Silver mica: 18 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.
±2%, 250 VDCW; sim to	C227LL	19A116656P10J0	Ceramic disc: 10 pf ±0.5 pf, 250 VDCW; sim to 0 PPM.	C239	19A116655P20	Ceramic disc: 1000 pf ±10%, 1000 VDCW; sim to RMC Type JF Discap.	C256	19A116655P20	Ceramic disc: 1000 pf ±10%, 1000 VDCW; sim to RMC Type JF Discap.
±2%, 250 VDCW; sim to	C227L	19A116952P20	Silver mica: 20 pf ±0.5 pf, 250 VDCW; sim to Underwood Type J1HF.	C240	7489162P9	Silver mica: 18 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.	C257	5496267P13	Tantalum: 2.2 µf ±20%, 20 VDCW; sim to Sprague Type 150D.
±2%, 250 VDCW; sim to	C227M	19A116952P19	Silver mica: 19 pf ±0.5 pf, 250 VDCW; sim to Underwood Type J1HF.	C241LL	19A116679P13D	Mica: 13 pf ±.5 pf, 250 VDCW.	C258LL	19A116952P31	Silver mica: 31 pf ±2%, 250 VDCW; sim to
±2%, 250 VDCW; sim to	С227Н	19A116952P17	Silver mica: 17 pf ±0.5 pf, 250 VDCW; sim to Underwood Type J1HF.	C241L C241M	19A116679P10D 19A116679P9D	Mica: 10 pf ±.5 pf, 250 VDCW. Mica: 9 pf ±.5 pf, 250 VDCW.	C258L	19A116952P23	Underwood Type J1HF. Silver mica: 23 pf ±0.5 pf, 250 VDCW; sim to
±0.5 pf, 500 VDCW, temp	C228LL	19A116656P10J0	Ceramic disc: 10 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.	C241H	19A116679P8D	Mica: 8 pf ±.5 pf, 250 VDCW.	C258M*	19A116952P23	Underwood Type J1HF. Silver mica: 23 pf ±0.5 pf, 250 VDCW; sim to
±0.5 pf, 500 VDCW, temp	C228L	19A116952P20	Silver mica: 20 pf ±0.5 pf, 250 VDCW; sim to Underwood Type J1HF.	C242	19A116656P24J0	Ceramic disc: 24 pf ±5%, 500 VDCW, temp coef 0 PPM.			Underwood Type JlHF. Earlier than REV A:
±0.5 pf, 500 VDCW, temp	C228M	19A116952P19	Silver mica: 19 pf ±0.5 pf, 250 VDCW; sim to Underwood Type J1HF.	C243LL	19A116952P31	Silver mica: 31 pf ±2%, 250 VDCW; sim to Underwood Type J1HF.		19A116952P22	Silver mica: 22 pf ±0.5 pf, 250 VDCW; sim to Underwood Type J1HF.
±0.5 pf, 500 VDCW, temp	C228H	19A116952P17	Silver mica: 17 pf ±0.5 pf, 250 VDCW; sim to Underwood Type J1HF.	C243L	19A116952P25	Silver mica: 25 pf ±2%, 250 VDCW; sim to Underwood Type J1HF.	С258Н	19A116952P20	Silver mica: 20 pf ±0.5 pf, 250 VDCW; sim to Underwood Type J1HF.
±0.5 pf, 250 VDCW; sim to	C229LL	19A116656P10J0	Ceramic disc: 10 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.	C243M	19A116952P20	Silver mica: 20 pf ±0.5 pf, 250 VDCW; sim to Underwood Type J1HF.	C259LL	19A116655P18	Ceramic disc: 680 pf ±10%, 1000 VDCW; sim to RMC Type JF Discap.
±0.5 pf, 250 VDCW; sim to	C229L	19A116952P20	Silver mica: 20 pf ±0.5 pf, 250 VDCW; sim to Underwood Type J1HF.	C243H	19A116952P19	Silver mica: 19 pf ±0.5 pf, 250 VDCW; sim to Underwood Type J1HF.	C259L	19A116656P24J0	Ceramic disc: 24 pf ±5%, 500 VDCW, temp coef 0 PPM.
±0.5 pf, 250 VDCW; sim to	C229M	19A116952P19	Silver mica: 19 pf ±0.5 pf, 250 VDCW; sim to Underwood Type J1HF.	C244	19A116655P20	Ceramic disc: 1000 pf ±10%, 1000 VDCW; sim to RMC Type JF Discap.	C259≝	19A116655P18	Ceramic disc: 680 pf ±10%, 1000 VDCW; sim to RMC Type JF Discap.
±0.5 pf, 250 VDCW; sim to	С229Н	19A116952P17	Silver mica: 17 pf ±0.5 pf, 250 VDCW; sim to Underwood Type J1HF.	C245	5496267P13	Tantalum: 2.2 μf $\pm 20\%$, 20 VDCW; sim to Spragee . Type 150D.	С259Н	19A116655P18	Ceramic disc: 680 pf ±10%, 1000 VDCW; sim to RMC Type JF Discap.
±0.5 pf, 500 VDCW, temp	C230LL	19Al16656P5J0	Ceramic disc: 5 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.	C246	7489162P9	Silver mica: 18 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.	C260LL	19A116655P18	Ceramic disc: 680 pf ±10%, 1000 VDCW; sim to RMC Type JF Discap.
±0.5 pf, 500 VDCW, temp	C230L	19A116952P10	Silver mica: 10 pf ±0.5 pf, 250 VDCW; sim to Underwood Type J1HF.	C247LL	19A116952P18	Silver mica: 18 pf ±2%, 250 VDCW; sim to Underwood Type JlhF.	C260L	19A116656P24J0	Ceramic disc: 24 pf ±5%, 500 VDCW, temp coef 0 PPM.
±0.5 pf, 500 VDCW, temp	C230M	19A116952P9	Silver mica: 9 pf ±0.5 pf, 250 VDCW; sim to Underwood Type J1HF.	C247L	19A116952P15	Silver mica: 15 pf ±2%, 250 VDCW; sim to Underwood Type J1HF.	C260M	5496218P249	Ceramic disc: 27 pf ±5%, 500 VDCW, temp coef -80 PPM.
±0.5 pf, 500 VDCW, temp	С230Н	19A116952P9	Silver mica: 9 pf ±0.5 pf, 250 VDCW; sim to Underwood Type J1HF.	C247M	19A116952P13	Silver mica: 13 pf ±2%, 250 VDCW; sim to Underwood Type J1HF.	С260Н	5496218P249	Ceramic disc: 27 pf ±5%, 500 VDCW, temp coef -80 PPM,
±0.5 pf, 250 VDCW; sim to	C231LL	19A116656P24J0	Ceramic disc: 24 pf ±5%, 500 VDCW, temp coef 0 PPM.	C247H	19A116952P11	Silver mica: 11 pf ±2%, 250 VDCW; sim to Underwood Type J1HF.	C261LL	19A116952P42	Silver mica: 42 pf ±2%, 250 VDCW; sim to Underwood Type J1HF.
t0.5 pf, 250 VDCW; sim to	C231L	19A116655P20	Ceramic disc: 1000 pf ±10%, 1000 VDCW; sim to RMC Type JF Discap.	C248LL	5496218P249	Ceramic disc: 27 pf ±5%, 500 VDCW, temp coef -80 PPM.	C261L	19A116952P30	Silver mica: 30 pf ±2%, 250 VDCW; sim to Underwood Type JlHF.
t0.5 pf, 250 VDCW; sim to	C231M	19A116655P20	Ceramic disc: 1000 pf ±10%, 1000 VDCW; sim to RMC Type JF Discap.	C248L	5496218P249	Ceramic disc: 27 pf ±5%, 500 VDCW, temp coef -80 PPM.	C261M	19A116952P30	Silver mica: 30 pf ±2%, 250 VDCW; sim to Underwood Type JlHF.
t0.5 pf, 250 VDCW; sim to	С231Н	19A116655P20	Ceramic disc: 1000 pf ±10%, 1000 VDCW; sim to RMC Type JF Discap.	C248M	5496218P249	Ceramic disc: 27 pf ±5%, 500 VDCW, temp coef -80 PPM.	С261Н .	19Al16952P27	Silver mica: 27 pf ±2%, 250 VDCW; sim to Underwood Type J1HF.
:0.5 pf, 500 VDCW, temp	C232L	19A116656P8J0	Ceramic disc: 8 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.	C248H	5496218P249	Ceramic disc: 27 pf ±5%, 500 VDCW, temp coef -80 PPM.	C262LL	19A116952P31	Silver mica: 31 pf ±2%, 250 VDCW; sim to Underwood Type J1HF.
0.5 pf, 500 VDCW, temp	C232M	19A116656P7J0	Ceramic disc: 7 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.	C249LL	19A116952P39	Silver mica: 39 pf ±2%, 250 VDCW; sim to Underwood Type J1HF.	C262L	19A116952P23	Silver mica: 23 pf ±0.5 pf, 250 VDCW; sim to Underwood Type J1HF.
:0.5 pf, 500 VDCW, temp	С232Н	19A116656P6J0	Ceramic disc: 6 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.	C249L	19A116952P30	Silver mica: 30 pf ±2%, 250 VDCW; sim to Underwood Type JlHF.	C262M*	19A116952P23	Silver mica: 23 pf ±0.5 pf, 250 VDCW; sim to
0.5 pf, 500 VDCW, temp	C233L	19A116656P8J0	Ceramic disc: 8 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.	C249M	19A116952P28	Silver mica: 28 pf ±2%, 250 VDCW; sim to Underwood Type JlHr.	. [Underwood Type JlHF. Earlier than REV A:
±2%, 250 VDCW; sim to	C233M	19A116656P7J0	Ceramic disc: 7 pf ±0.5 pf, 500 VDCW, temp coef	С249Н	19A116952P26	Silver mica: 26 pf ±2%, 250 VDCW; sim to Underwood Type JlHF.		19A116952P22	Silver mica: 22 pf ± 0.5 pf, 250 VDCW; sim to Underwood Type JlHF.
2%, 250 VDCW; sim to	С233Н	19A116656P6J0	O PPM. Ceramic disc: 6 pf ±0.5 pf, 500 VDCW, temp coef	C250	19A116655P20	Ceramic disc: 1000 pf ±10%, 1000 VDCW; sim to RMC Type JF Discap.	C262H	19A116952P20	Silver mica: 20 pf ±0.5 pf, 250 VDCW; sim to Underwood Type JlHF.
2%, 250 VDCW; sim to	C234	7489162P9	0 PPM. Silver mica: 18 pf ±5%, 500 VDCW; sim to	C251	5496267P13	Tantalum: 2.2 µf ±20%, 20 VDCW; sim to Sprague Type 150D.	C263LL	19A116655P18	Ceramic disc: 680 pf ±10%, 1000 VDCW; sim to RMC Type JF Discap.
.,, ,	C235	19A116655P20	Electro Motive Type DM-15. Ceramic disc: 1000 pf ±10%, 1000 VDCW;	C252	19A116655P20	Ceramic disc: 1000 pf ±10%, 1000 VDCW; sim to RMC Type JF Discap.	C263L	19A116656P24J0	Ceramic disc: 24 pf ±5%, 500 VDCW, temp coef 0 PPM.
			sim to RMC Type JF Discap.				C263M	19A116655P18	Ceramic disc: 680 pf ±10%, 1000 VDCW; sim to RMC Type JF Discap.
							С263Н	19A116655P18	Ceramic disc: 680 pf ±10%, 1000 VDCW; sim to RMC Type JF Discap.
			. ,				C264	7489162P9	Silver mica: 18 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.

╛╵	SYMBOL	GE PART NO.	DESCRIPTION		SYMBOL	GE PART NO.	
	C265	19A116655P20	Ceramic disc: 1000 pf ±10%, 1000 VDCW; sim to RMC Type JF Discap.		C290LL	19A116952P11	
	C266	5496267P13	Tantalum: 2.2 µf ±20%, 20 VDCW; sim to Sprague Type 150D.		C290L .	19A116952P10	
	C267	7489162P9	Silver mica: 18 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.	$ \ $	C290M	19A116952P9	
	C268LL	19A116952P42	Silver mica: 42 pf ±2%, 250 VDCW; sim to Underwood Type JlHF.	$\ \ $	С290Н	19A116952P9	
	C268L	19Al16952P30	Silver mica: 30 pf ±2%, 250 VDCW; sim to Underwood Type J1HF.	П	C291 and C292	19A116655P20	
	C268M 19A116952P30 Silver mica: 30 pf ±2%, 250 VDCW; sim to Underwood Type JlHF.		Silver mica: 30 pf ±2%, 250 VDCW; sim to	Ш	C293	19A116679P220K	
	C268H	19A116952P27	Silver mica: 27 pf ±2%, 250 VDCW; sim to Underwood Type J1HF.	П	C294	19A116655P8	
	C269	C269 19A116655P20 Ceramic disc: 1000 pf ±10%, 1000 VDCW; sim to RMC Type JF Discap.		Ы	C295 and C296	19A116655P18	
	1 1 1		Ceramic disc: 1000 pf ±10%, 1000 VDCW:	Ш	C4201	19A116655P18	
	C271	I I		П	C4202 C4203	1941160802104	
	C272	19A116655P20	Ceramic disc: 1000 pf ±10%, 1000 VDCW; sim to RMC Type JF Discap.	П	C4204	19A116655P20	
	C273 and	19A116655P8	Ceramic disc: 150 pf ±10%, 1000 VDCW; sim to RMC Type JF Discap.	П	C4205	19A116080P104	
	C274 C275LL	19A116655P20	Ceramic disc: 1000 pf ±10%, 1000 VDCW;	П	C4206	\$496267P14	
	C275L	sim to RMC Type JF Discap. 19A116655P20		П	C4207 and C4208	19A116080P104	
	C275M	19A116655P20	sim to RMC Type JF Discap.		C4209 and	19A116655P8	
	С275Н	19A116656P27J0	sim to RMC Type JF Discap. Ceramic disc: 27 pf ±5%, 500 VDCW, temp coef	$\ $	C4210 C4211	19A116655P20	
H	C276	19A116655P20	O PPM. Ceramic disc: 1000 pf ±10%, 1000 VDCW;	Ш	C4211	19A116655P18	
	thru C280		sim to RMC Type JF Discap.	Н	C4212L		
	C281 thru C284	19A116679P220K	Mica: 220 pf ±10%, 250 VDCW.	П	C4212LL	19A116655P8	
	C285	5496218P45	Ceramic disc: 18 pf ±5%, 500 VDCW, temp coef 0 PPM.	П	C4212H	19A116655P18	
	C286LL	19A116952P11	Silver mica: 11 pf ±0.5 pf, 250 VDCW; sim to Underwood Type J1HF.	П	C4213LL	19A116656P6J0	
	C286L	86L 19A116952P10 Silver mica: 10 pf ±0.5 pf, 250 VDCW; sim to Underwood Type J1HF. 86M 19A116952P9 Silver mica: 9 pf ±0.5 pf, 250 VDCW; sim to Underwood Type J1HF.			C4214LL	19A116656P10.10	
	C286M			$\ \ $	C4215LL		
	C286H			$ \ $	C4216LL	19A116656P10J0 19A116656P10J0	
	C287LL	19A116952P22	Silver mica: 22 pf ±0.5 pf, 250 VDCW; sim to Underwood Type J1HF.	Ш	C4217LL	19A116656P6J0	
	C287L	L 19A116952P20 Silver mica: 20 pf ±0.5 pf, 250 VDCW; sim to Underwood Type J1HF.		Ш	C4217hL		
П	C287M				C4218M	5496218P249	
П	С287Н	19A116952P17	Silver mica: 17 pf ±0.5 pf, 250 VDCW; sim to	$\ \ $		5496218P249	
	C288LL	19A116952P22	Silver mica: 22 pf ±0.5 pf, 250 VDCW; sim to Underwood Type JlHF.		C4219H	5491238P12	
П	C288L	19A116952P20	Silver mica: 20 pf ±0.5 pf, 250 VDCW; sim to Underwood Type J1HF.	$\ \ $			
	C288M	19A116952P17	Silver mica: 17 pf ±0.5 pf, 250 VDCW; sim to Underwood Type JlHF.		CR201 thru CR206	19A115250P1	
П	C288H	19A116952P17	Silver mica: 17 pf ±0.5 pf, 250 VDCW; sim to Underwood Type J1HF.	H			
П	C289LL	19A116952P22	Silver mica: 22 pf ±0.5 pf, 250 VDCW; sim to Underwood Type JlHF.		J201 thru	19A116832P1	
П	C289L	19A116952P20	Silver mica: 20 pf ±0.5 pf, 250 VDCW; sim to	ľ	J203 J204	19B219374G1	
	C289M	19A116952P17	Underwood Type J1HF. Silver mica: 17 pf ±0.5 pf, 250 VDCW; sim to Underwood Type J1HF.		J208	4033513P4	
	С289Н	19A116952P17	Silver mica: 17 pf ±0.5 pf, 250 VDCW; sim to Underwood Type J1HF.		K201	19A116722P1	

DESCRIPTION		SYMBOL	GE P	
Silver mica: ll pf ±0.5 pf, 250 VDCW; sim to				
Underwood Type J1HF. Silver mica: 10 pf ±0.5 pf, 250 VDCW; sim to		L201	19A129	
Underwood Type J1HF.		L202	748807	
Silver mica: 9 pf ±0.5 pf, 250 VDCW; sim to Underwood Type J1HF.		L203LL	19A129	
Silver mica: 9 pf ±0.5 pf, 250 VDCW; sim to Underwood Type JlHF.		L203L	19A129	
Ceramic disc: 1000 pf ±10%, 1000 VDCW; sim to RMC Type JF Discap.		L203M	19A129	
		L203H L204	19A129	
Mica: 220 pf ±10%, 250 VDCW. Ceramic disc: 150 pf ±10%, 1000 VDCW:		L205	19A129 19B219	
sim to RMC Type JF Discap.		L206	748807	
Ceramic disc: 680 pf ±10%, 1000 VDCW; sim to RMC Type JF Discap.		L207LL	19B209	
Ceramic disc: 680 pf ±10%, 1000 VDCW; sim to RMC Type JF Discap.		L207L	748807	
Polyester: 0.033 µf ±10%, 50 VDCW.		L207M	748807	
Ceramic disc: $1000 \text{ pf } \pm 10\%$, 1000 VDCW ; sim to RMC Type JF Discap.		L207H	748807	
Polyester: 0.033 μf ±10%, 50 VDCW.		L208	198219	
Tantalum: 15 μf $\pm 20\%,$ 20 VDCW; sim to Sprague Type 150D.		L209	748807	
Polyester: 0.033 μf ±10%, 50 VDCW.		L210LL	748807	
Ceramic disc: 150 pf ±10%, 1000 VDCW; sim to RMC Type JF Discap.		L210L	748807	
Sim to RMC Type JF Discap. Ceramic disc: 1000 pf ±10%, 1000 VDCW;		L210M	748807	
ceramic disc: 680 pf ±10%, 1000 vDcw; sim to RMC Type JF Discap.		L210H	748807	
-		L211	198219	
sim to RMC Type JF Discap.		L213 L214	19A129 19B219	
Ceramic disc: 150 pf ±10%, 1000 VDCW; sim to RMC Type JF Discap.		L215LL	748807	
Ceramic disc: 680 pf \pm 10%, 1000 VDCW; sim to RMC Type JF Discap.		L215L	748807	
Ceramic disc: 6 pf ± 0.5 pf, 500 VDCW, temp coef 0 PPM.		L215M	748807	
Ceramic disc: 10 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.	ı	L215H	748807	
Ceramic disc: 10 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.	and the same	L216	198219	
Ceramic disc: 10 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.		L217	19A129	
Ceramic disc: 6 pf ± 0.5 pf, 500 VDCW, temp coef 0 PPM.		L218LL	748807	
Ceramic disc: 27 pf ±5%, 500 VDCW, temp coef -80 PPN.			, 748807	
Ceramic disc: 27 pf ±5%, 500 VDCW, temp coef -80 PPM.		L218M	748807	
Ceramic disc: 2 pf ±0.25 pf, 500 VDCW, temp coef -80 ±120 PPM.		L218H	748807	
DIODES AND RECTIFIERS	١	L219 L220	19A129 19A129	
Silicon.		L221LL	19C320	
		L221L	19C320	
JACKS AND RECEPTACLES		L221M	19C320	
Receptacle, coaxial: sim to Cinch 14H11613.	1	L221H L222LL	19C320	
	ļ	L222L	190320	
Connector: 9 contacts.		L222M	19C320	
Contact, electrical: sim to Bead Chain L93-3.		L222H	19C320	
	П	L223LL	19C320	
Hermetic sealed: 125 ohms ±20%, 1 form C contact, 9.6 to 15.8 VDC (over the temp range indicated).	:			
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SYMBOL	GE PART NO.	DESCRIPTION	["	SYMBOL	GE PART NO.	DESCRIPTION		SYMBOL	
		INDUCTORS		L223L	19C320623P2	Coil.	: -		ſ
L201	19A129773G1	Coil.	П	L223M	19C320623P2	Coil.		W202	ı
L202	7488079118	Choke, RF: 15.0 µh ±10%, 1.20 ohms DC res max;	П	L223H	19C320623P2	Coil.		W203	ı
L203LL	19A129233P4	sim to Jeffers 4421-9K. Coil.	1	L224LL	19C320623P1	Coil.		W204	ı
L203L	19A129233P2	Coil.	Ш	L224L	19C320623P2	Coil.		W205	ı
L203M	19A129233P3	Coil.	П	L224M L224H	19C320623P2 19C320623P2	Coil.		W206	ı
L203H	19A129233P3	Coil.	П	LSETH	190320023P2	con.		W207	ı
L204	19A129773G1	Coil.	Н			TRANSISTORS		W208 thru	ı
L205	19B219457P4	Coil.	Ш	Q207 Q208	19A116201P1	Silicon, NPN.		W237 W238	ı
L206	7488079140	Choke, RF: 5.60 µh ±10%, 0.15 ohms DC res max; sim to Jeffers 4422-1K.	П	Q208 Q209	19A115910P1 19A115768P1	Silicoh, NPN; sim to Type 2N3904. Silicor, PNP; sim to Type 2N3702.			ı
L207LL	19B209420P125	Coil, RF: 10.0 µh ±10%, 3.10 ohms DC res max; sim to Jeffers 4446-4.	Н	thru Q211	1	olitor, far, sin to type 285702.	П	Z201	
L207L	7488079118	Choke, RF: 15.0 μh $\pm 10\%$, 1.20 ohms DC res max; sim to Jeffers 4421-9.	П	Q212 Q213	19A115910P1 19A115779P1	Silicor, NPN; sim to Type 2N3904.			ı
L207 M	748807918	Choke, RF: 15.0 µh ±10%, 1.20 ohms DC res max; sim to Jeffers 4421-9,	П	4520	134110713F1	Silico:, PNP; sim to Type 2N3251.	1		
L207H	7488079118	Choke, RF: 15.0 µh ±10%, 1.20 ohms DC res max; sim to Jeffers 4421-9.	П	R201	3R152P102J	RESISTORS Composition: 1000 ohms ±5%, 1/4 w.			ı
L208	19B219457p3	Coil.	П	R202	3R77P101J	Composition: 100 ohms ±5%, 1/2 w.	1	C297 and	ı
L209	7488079140	Choke, RF: 5.60 µh ±10%, 0.15 ohms DC res max;	:	R203	3R77P150J	Composition: 15 ohms ±5%, 1/2 w.		C298	ı
L210LL	7488079F18	sim to Jeffers 4422-1. Choke, RF: 15.0 \(\mu \)h \(\pm \)10%, 1.20 \(\text{ohms DC res max} \);	l.	R204	19B209022P131	Wirewound: 4.7 ohms ±10%, 2 w; sim to IRC Type BVH.		C299	ı
L210L	74880791140	sim to Jeffers 4421-9. Choke, RF: 5.60 µh ±10%, 0.15 ohms DC res max;	П	R205	3R152P102J	Composition: 1000 ohms ±5%, 1/4 w.			ı
L210M	7488079 P 18	sim to Jeffers 4422-1.	1	R206 and R207	3R77P100J	Composition: 10 ohms ±5%, 1/2 w.	l	CR295	ı
L210H		Choke, RF: 15.0 μh $\pm 10\%$, 1.20 ohms DC res max; sim to Jeffers 4421-9.	П	R209	3R78P101J	Composition: 100 ohms ±5%, 1 w.	٠		ı
	7488079P18	Choke, RF: 15.0 μh $\pm 10\%$, 1.20 ohms DC res max; sim to Jeffers 4421-9.	П	R210 and	3R78P100J	Composition: 10 ohms ±5%, 1 w.			ı
L211 L213	19B219457P3 19A129346G1	Coil.	П	R211 R212	3R78P101J	Composition: 100 ohms ±5%, 1 w.			ı
L213	198129346G1 19B219457P3	Coil.	П	R213	19C320212P2	Shunt resistor.	:		ı
L215LL	7488079P18	Choke, RF: 15.0 µh ±10%, 1.20 ohms DC res max;	П	and R214					ı
L215L	7488079 P 40	sim to Jeffers 4421-9. Choke, RF: 5.60 µh ±10%, 0.15 ohms DC res max;	П	R215	3R152P510J	Compos.tion: 51 ohms ±5%, 1/4 w.			ı
L215M	7488079P18	sim to Jeffers 4422-1.	П	R216 R217	3R152P200J 3R77P470J	Composition: 20 ohms ±5%, 1/4 w. Composition: 47 ohms ±5%, 1/2 w.			
L215H		Choke, RF: 15.0 μ h \pm 10%, 1.20 ohms DC res max; sim to Jeffers 4421-9.	П	R218	3R152P153J	Composition: 15,000 ohms ±5%, 1/4 w.			ı
	7488079P18	Choke, RF: 15.0 μh $\pm 10\%$, 1.20 ohms DC res max; sim to Jeffers 4421-9.	П	R219	3R152P682J	Composition: 6800 ohms ±5%, 1/4 w.			ı
L216 L217	19B219457P3 19A129346G1	Coil.	П	R220 and R221	3R152P101J	Composition: 100 ohms ±5%, 1/4 w.			ı
L218LL	7488079 P 18	Coil.	П	R222	19A116278P233	Metal film: 2150 ohms ±2%, 1/2 w.			ı
		Choke, RF: 15.0 μ h \pm 10%, 1.20 ohms DC res max; sim to Jeffers 4421-9.	П	R223	19A116278P217	Metal film: 1470 ohms ±2%, 1/2 w.			ı
L218L	, 7488079P40	Choke, RF: 5.60 μh ±10%, 0.15 ohms DC res max; sim to Jeffers 4422-1.		R224 and	19A116278P261	Metal film: 4220 ohms ±2%, 1/2 w.			
L218M	7488079 P 18	Choke, RF: 15.0 µh ±10%, 1.20 ohms DC res max; sim to Jeffers 4421-9.	П	R225 R226	19Al16559P102	Variable, cermet: 5000 chms ±20%, .5 w; sim to			
L218H	7488079P18	Choke, RF: 15.0 µh ±10%, 1.20 chms DC res max; sim to Jeffers 4421-9.	ľ	R227	3R77P121J	CIU DE IES 300.			
L219	19A129774P1	Coil.	П	R228	3R77P471J	Composition: 120 ohms ±5%, 1/2 w. Composition: 470 ohms ±5%, 1/2 w.			ı
L220	19A129773G1	Coil.	П	R229	3R152P182J	Composition: 1800 ohms ±5%, 1/4 w.			ı
L221LL	19C320623P1	Coil.	П	R230	3R152P12OJ	Composition: 12 ohms ±5%, 1/4 w.	1		ı
L221L L221M	19C320623P2	Coil.	П	R231	19A116278P269	Metal film: 5110 ohms ±2%, 1/2 w.			ı
L221H	19C320623P2 19C320623P2	Coil.	П	R232	3R152P682J	Composition: 6800 ohms ±5%, 1/4 w.			ı
L222IL	19C320623P1	Coil.	П	R233	3R152P681J	Composition: 680 ohms ±5%, 1/4 w.			
L222L	19C320623P2	Coil.	П	R234	3R77P561J	Composition: 560 ohms ±5%, 1/2 w.	1		
L222M	19C320623P2	Coil,	Ш			VOLTAGE REGULATORS			
L222H	19C320623P2	Coil.	Ы	VR201	4036887Pl	Silicm, Zener.	1		
L223LL	19C320623P1	Coil.		VR202	4036887P5	Silicm, Zener.			
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GE PART NO. DESCRIPTION 19A129571P1 19B219995P1 19B219995P2 19B219995P3 19B219986P1 19B219995P5 (Part of printed wiring board 19D417162P1 for L, M, H and 19D417402P1 for LL). 19B219995P4 19B219649G3 HEAT SINK ASSEMBLY 19B219688G5 19Al16708Pl Ceramic, feed-thru: 0.01 µf +125 ~0%, 500 VDCW; sim to Erie Style 327. Electrolytic: 200 µf +150% -10%, 18 VDCW; sim to Mallory Type TT. 19A115680P10 - - - - - DIODES AND RECTIFIERS - - - - -19Al16783P1 ----- MISCELLANEOUS ----19D416712P5 Insulation. (Located under component board). 19B201074P320 Tap screw, Phillips POZIDRIV®: No. 6-32 x 1-1/4. (Used with Filter casting). 5492178P2 Washer, spring tension. (Used with Q201-Q206). N207P15C6 Hexnut: No. 8-32. (Used with Q201-Q206).
19A116022P1 Insulator, bushing. (Used with Q215). 19Al16023Pl Insulator, plate. (Used with Q215). N5602P015 "O" Ring. (Used with Q215). N402P7C6 Washer: No. 6. (Used with Q215). 19Al29888Pl Insulator. (Used with Q215 under washer). 19A129661P1 Insulator. (Located by L295, L296). 19Al29434Pl Washer. (Used with C297, C298). 19B209502Pl Terminal, stud. (Used with C286-C290).

PRODUCTION CHANGES

Changes in the equipment to improve performance or to simplify circuits are identified by a "Revision Letter", which is stamped after the model number of the unit. The revision stamped on the unit includes all previous revisions. Refer to the Parts List for descriptions of parts affected by these revisions.

REV. A: Power Amplifier Component Board 19D417166G3. To increase Power Output. Changed C258 and C262.